2020

Panasonic INDUSTRY

Fixed Resistors

Products Catalog





Guidelines and precautions regarding the technical information and use of our products described in this online catalog.

- If you want to use our products described in this online catalog for applications requiring special qualities or reliability, or for applications where the failure or malfunction of the products may directly jeopardize human life or potentially cause personal injury (e.g. aircraft and aerospace equipment, traffic and transportation equipment, combustion equipment, medical equipment, accident prevention, anti-crime equipment, and/or safety equipment), it is necessary to verify whether the specifications of our products fit to such applications. Please ensure that you will ask and check with our inquiry desk as to whether the specifications of our products fit to such applications use before you use our products.
- The quality and performance of our products as described in this online catalog only apply to our products when used in isolation. Therefore, please ensure you evaluate and verify our products under the specific circumstances in which our products are assembled in your own products and in which our products will actually be used.
- If you use our products in equipment that requires a high degree of reliability, regardless of the application, it is recommended that you set up protection circuits and redundancy circuits in order to ensure safety of your equipment.
- The products and product specifications described in this online catalog are subject to change for improvement without prior notice. Therefore, please be sure to request and confirm the latest product specifications which explain the specifications of our products in detail, before you finalize the design of your applications, purchase, or use our products.
- The technical information in this online catalog provides examples of our products' typical operations and application circuits. We do not guarantee the non-infringement of third party's intellectual property rights and we do not grant any license, right, or interest in our intellectual property.
- If any of our products, product specifications and/or technical information in this online catalog is to be exported or provided to non-residents, the laws and regulations of the exporting country, especially with regard to security and export control, shall be observed.

< Regarding the Certificate of Compliance with the EU RoHS Directive/REACH Regulations>

- The switchover date for compliance with the RoHS Directive/REACH Regulations varies depending on the part number or series of our products.
- When you use the inventory of our products for which it is unclear whether those products are compliant with the RoHS Directive/REACH Regulation, please select "Sales Inquiry" in the website inquiry form and contact us.

We do not take any responsibility for the use of our products outside the scope of the specifications, descriptions, guidelines and precautions described in this online catalog.



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Safety Precautions (Common precautions for Fixed Resistors)

- When using our products, no matter what sort of equipment they might be used for, be sure to make a written agreement on the specifications with us in advance. The design and specifications in this catalog are subject to change without prior notice.
- Do not use the products beyond the specifications described in this catalog.
- This catalog explains the quality and performance of the products as individual components. Before use, check and evaluate their operations when installed in your products under the actual conditions for use.
- Install the following systems for a failsafe design to ensure safety if these products are to be used in equipment
 where a defect in these products may cause the loss of human life or other significant damage, such as
 damage to vehicles (automobile, train, vessel), traffic lights, medical equipment, aerospace equipment,
 electric heating appliances, combustion/gas equipment, rotating equipment, and disaster/crime prevention
 equipment.
- * Systems equipped with a protection circuit and a protection device.
- * Systems equipped with a redundant circuit or other system to prevent an unsafe status in the event of a single fault.
- * Systems equipped with an arresting the spread of fire or preventing glitch.

(1) Precautions for use

Panasonic INDUSTRY

- These products are designed and manufactured for general and standard use in general elec tron ic equipment. (e.g. AV equipment, home electric appliances, office equipment, information and communication equipment) For applications in which special quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or cause threat of personal injury (such as for aircraft and aerospace equipment, traffic and transport equipment, combustion equipment, medical equipment, accident prevention and anti-theft devices, and safety equipment), please be sure to consult with our sales representative in advance and to exchange product specifications which conform to such applications.
- These products are not intended for use in the following special conditions. Before using the products, carefully check the effects on their quality and performance, and determine whether or not they can be used.
 - 1. In liquid, such as water, oil, chemicals, or organic solvent.
 - 2. In direct sunlight, outdoors, or in dust.
 - 3. In salty air or air with a high concentration of corrosive gas, such as Cl_2 , H_2S , NH_3 , SO_2 , or NO_X .
 - 4. Electric Static Discharge (ESD) Environment.
 - These components are sensitive to static electricity and can be damaged under static shock (ESD). Please take measures to avoid any of these environments.
 - Smaller components are more sensitive to ESD environment.
 - 5. Electromagnetic and Radioactive Environment.
 - Avoid any environment where strong electromagnetic waves and radiation exist.
 - 6. In an environment where these products cause dew condensation.
 - 7. Sealing or coating of these products or a printed circuit board on which these products are mounted, with resin or other materials.
- These products generate Joule heat when energized. Carefully position these products so that their heat will not affect the other components.
- Carefully position these products so that their temperatures will not exceed the category temperature range due to the effects of neighboring heat-generating components. Do not mount or place heat-generating components or inflammables, such as vinyl-coated wires, near these products.
- Note that non-cleaning solder, halogen-based highly active flux, or water-soluble flux may deteriorate the performance or reliability of the products.
- Carefully select a flux cleaning agent for use after soldering. An unsuitable agent may deteriorate the performance or reliability. In particular, when using water or a water-soluble cleaning agent, be careful not to leave water residues. Otherwise, the insulation performance may be deteriorated.
- Do not apply flux to these products after soldering. The activity of flux may be a cause of failures in these products.
- Refer to the recommended soldering conditions and set the soldering condition. High peak temperature or long heating time may impair the performance or the reliability of these products.
- Recommended soldering condition is for the guideline for ensuring the basic characteristics of the products, not for the stable soldering conditions. Conditions for proper soldering should be set up according to individual conditions.

- Do not reuse any products after removal from mounting boards.
- Do not drop these products. If these products are dropped, do not use them. Such products may have received mechanical or electrical damage.
- If any doubt or concern to the safety on these products arise, make sure to inform us immediately and conduct technical examinations at your side.

(2) Precautions for storage

The performance of these products, including the solderability, is guaranteed for a year from the date of arrival at your company, provided that they remain packed as they were when delivered and stored at a temperature of 5 °C to 35 °C and a relative humidity of 45 % to 85 %.

Even within the above guarantee periods, do not store these products in the following conditions. Otherwise, their electrical performance and/or solderability may be deteriorated, and the packaging materials (e.g. taping materials) may be deformed or deteriorated, resulting in mounting failures.

- In salty air or in air with a high concentration of corrosive gas, such as Cl₂, H₂S, NH₃, SO₂, or NO_X.
- 2. In direct sunlight.

(3) AEC-Q200 Compliant

The products are tested based on all or part of the test conditions and methods defined in AEC-Q200. Please consult with Panasonic for the details of the product specification and specific evaluation test results, etc., and please review and approve Panasonic's product specification before ordering.

<Package markings>

Package markings include the product number, quantity, and country of origin.

In principle, the country of origin should be indicated in English.



Safety Precautions (Common precautions for Surface Mount Resistors)

The following are precautions for individual products. Please also refer to the common precautions for Fixed Resistors in this catalog.

- Take measures against mechanical stress during and after mounting of Surface Mount Resistors (hereafter called the resistors) so as not to damage their electrodes and protective coatings. Be careful not to misplace the resistors on the land patterns. Otherwise, solder bridging may occur.
- Keep the rated power and ambient temperature within the specified derating curve. Some circuit boards, wiring patterns, temperatures of heat generated by adjacent components, or ambient temper a tures can become factors in the rise of the temperature of the resistors, regardless of the level of power applied. Therefore, check the conditions before use and op timize them so as not to damage the boards and peripheral components.
 - Make sure to contact us before using the resistors under special conditions.
- If a transient load (heavy load in a short time) like a pulse is expected to be applied, check and evaluate the operations of the resistors when installed in your products before use. Never exceed the rated power. Otherwise, the performance and/or reliability of the resistors may be impaired.
- Transient voltage If there is a possibility that the transient phenomenon (significantly high voltage applied in a short time) may occur or that a high voltage pulse may be applied, make sure to evaluate and check the characteristics of resistors mounted on your product rather than only depending on the calculated power limit or steady-state conditions.
- 5. If the resistors are to be used in high frequency circuits, carefully check the operation before use. Such circuits change the electrical characteristics of the resistors.
- Before using halogen-based or other high-activity flux, check the possible effects of the flux residues on the 6. performance and reliability of the resistors.
- 7. When soldering with a soldering iron, never touch the resistors'bodies with the tip of the soldering iron. When using a soldering iron with a high temperature tip, finish soldering as quickly as possible (within three seconds at 350 °C max.).
- Mounting of the resistors with excessive or insufficient wetting amount of solder may affect the connection reliability or the performance of the resistors. Carefully check the effects and apply a proper amount of solder for use.
- When the resistors' protective coatings are chipped, flawed, or removed, the characteristics of the 9. resistors may be impaired. Take special care not to apply mechanical shock during automatic mounting or cause damage during handling of the boards with the resistors mounted.
- 10. Do not apply shock to the resistors or pinch them with a hard tool (e.g. pliers and tweezers). Otherwise, the resistors' protective coatings and bodies may be chipped, affecting their performance.
- 11. Avoid excessive bending of printed circuit boards in order to protect the resistors from abnormal stress.
- 12. Do not immerse the resistors in solvent for a long time. Before using solvent, carefully check the effects of immersion.
- 13. Do not apply excessive tension to the terminals.



Thick Film Chip Resistors

Thick Film Chip Resistors

Series: ERJ XG, 1G, 2G, 3G, 6G, 8G, 14, 12, 12Z, 1T









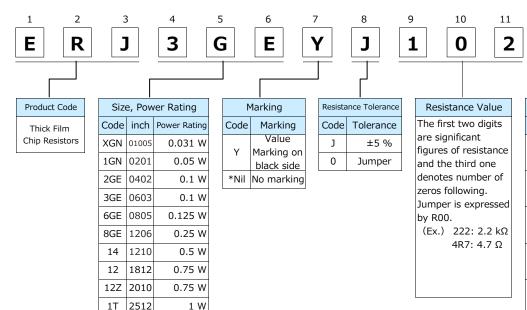
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Features

- Small size and lightweight
- High reliability...Metal glaze thick film resistive element and three layers of electrodes
- Compatible with placement machines ··· Taping packaging available
- Suitable for both reflow and flow soldering
- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant (except ERJXG)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

Series ERJXGN, 1GN, 2GE, 3GE, 6GE, 8GE, 14, 12, 12Z, 1T, ±5 %



^{*}Series XGN, 1GN and 2GE do not have value markings on the black side. Please omit the letter "Y" from the part number for these series of parts. The other part number factors will move up respectively.

	Packaging Methods									
Code	Packaging	Part No.								
Y	Pressed Carrier Taping W8P2, 20,000 pcs	FR1XGN								
U	Embossed Carrier Taping W4P1, 40,000 pcs	LIGAGIV								
U	Pressed Carrier Taping 2 mm pitch, 15,000 pcs	ERJ1GN								
X	Punched Carrier Taping 2 mm pitch, 10,000 pcs	FR12GF								
Y	Punched Carrier Taping 2 mm pitch, 20,000 pcs	LIGZGL								
٧	Punched Carrier Taping 4 mm pitch, 5,000 pcs	ERJ3GE ERJ6GE ERJ8GE								
U	Embossed Carrier Taping 4 mm pitch, 5,000 pcs	ERJ14 ERJ12 ERJ12Z								
	Embossed Carrier Taping 4 mm pitch, 4,000 pcs	ERJ1T								

Ratings

[For Resistor]

Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJXG (01005)	0.031	15	30	±5	1 to 1 M	(E24)	R<10 Ω : -100 to +600 10 Ω to 100 Ω : \pm 300 100 Ω≤R : \pm 200	-55 to +125	-
ERJ1G (0201)	0.05	25	50	±5	1 to 10 M	(E24)		-55 to +125	Grade 1
ERJ2G (0402)	0.1	50	100	±5	1 to 10 M	(E24)	R<10 Ω:	-55 to +155	Grade 0
ERJ3G (0603)	0.1	75	150	±5	1 to 10 M	(E24)	-100 to +600	-55 to +155	Grade 0
ERJ6G (0805)	0.125	150	200	±5	1 to 10 M	(E24)	10 Ω to 1 M Ω :	-55 to +155	Grade 0
ERJ8G (1206)	0.25	200	400	±5	1 to 10 M	(E24)	±200	-55 to +155	Grade 0
ERJ14 (1210)	0.5	200	400	±5	1 to 10 M	(E24)	1 MΩ <r :<="" td=""><td>-55 to +155</td><td>Grade 0</td></r>	-55 to +155	Grade 0
ERJ12 (1812)	0.75	200	500	±5	1 to 10 M	(E24)	-400 to +150	-55 to +155	Grade 0
ERJ12Z (2010)	0.75	200	500	±5	1 to 10 M	(E24)		-55 to +155	Grade 0
ERJ1T (2512)	1	200	500	±5	1 to 1 M	(E24)		-55 to +155	Grade 0

- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

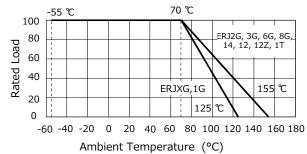
[For Jumper]

1. 0. 50.			
Part No.	Resistance(Ω)	Rated Current(A)	Maximum Overload Current (A) ⁽¹⁾
ERJXG		0.5	1
ERJ1G		0.5	1
ERJ2G		1	2
ERJ3G		1	2
ERJ6G	50 mΩ or less		
ERJ8G	50 11152 OF 1655		
ERJ14		2	4
ERJ12		2	4
ERJ12Z			
ERJ1T			

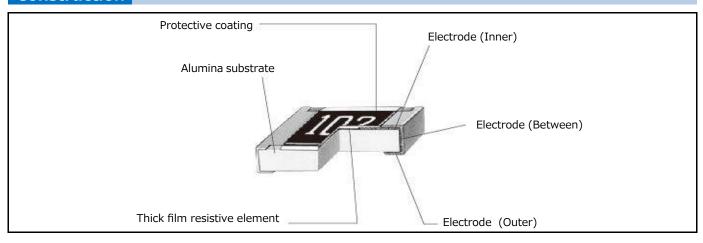
(1) Overload test current

Power Derating Curve

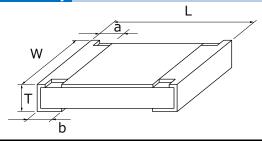
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.



Construction



Dimensions in mm (not to scale)



Part No.		Dimensions (mm)									
Part No.	L	W	a	b	Т	(g/1000 pcs)					
ERJXG	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04					
ERJ1G	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15					
ERJ2G	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8					
ERJ3G	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2					
ERJ6G	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4					
ERJ8G	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10					
ERJ14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16					
ERJ12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27					
ERJ12Z	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27					
ERJ1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45					

Performance

Test Item	Performance Re	equirements ⊿R	Test Conditions			
rest Item	Resistor type Jumper type		rest conditions			
Resistance	Within Specified Tolerance	50 mΩ or less	20 °C			
T. C. R.	Within Specified T. C. R.	$50 \ \text{m}\Omega$ or less	+25 °C/+155 °C (ERJXG,1G : +25 °C/+125 °C)			
Overload	±2 %	50 m Ω or less	Rated Voltage× 2.5, 5 s Jumper type: Max. Overload Current, 5 s			
Resistance to Soldering Heat	±1 %	50 mΩ or less	270 °C, 10 s			
Rapid Change of Temperature	±1 %	50 m Ω or less	-55 °C (30 min.) / +155 °C (ERJXG,1G: +125 °C) (30 min.), 100 cycles			
High Temperature Exposure	±1 %	50 mΩ or less	+155 °C (ERJXG,1G: +125 °C), 1000 h			
Damp Heat, Steady State	±1 %	50 m Ω or less	60 °C, 90 % to 95 %RH, 1000 h			
Load Life in Humidity	ife in Humidity ±3 % 50 mΩ or less		60 °C, 90 % to 95 %RH, Rated Voltage (Jumper type:			
			Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h 70 °C, Rated Voltage (Jumper type :Rated Current),			
Endurance at 70 °C	±3 %	50 m Ω or less	1.5 h ON / 0.5 h OFF cycle, 1000 h			



Precision Thick Film Chip Resistors

Precision Thick Film Chip Resistors

Series: ERJ XG, 1G

ERJ 1R, 2R, 3R, 6R

ERJ 3E, 6E, 8E, 14, 12, 1T









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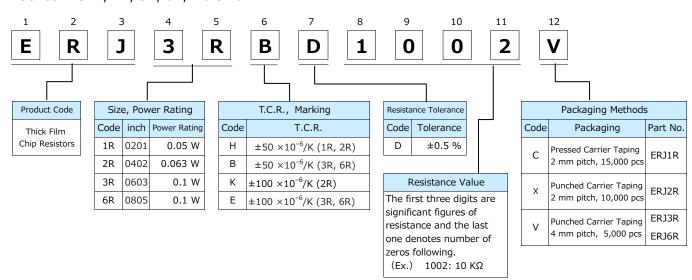
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Features

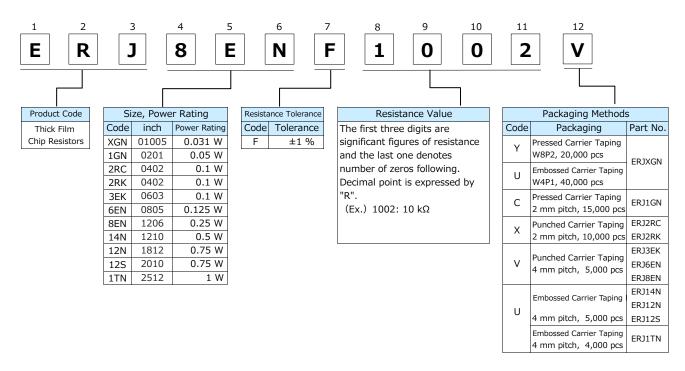
- Small size and lightweight
- High reliability...Metal glaze thick film resistive element and three layers of electrodes
- Compatible with placement machines ··· Taping packaging available
- Suitable for both reflow and flow soldering
- Low Resistance Tolerance :ERJXG, 1G, 2R, 3E, 6E, 8E, 14, 12, 1T : ±1 % ERJ1R, 2R, 3R, 6R : ±0.5 %
- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant (except ERJXG, ERJ1R)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

• Series ERJ1R, 2R, 3R, 6R, ±0.5 %



• Series ERJXGN, 1GN, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN, ±1 %



Ratings

<±0.5 %>

Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (°C)	AEC- Q200 Grade
ERJ1RH (0201)	0.05	15	30	±0.5	1 k to 1 M	(E24,E96)	±50	-55 to +125	-
ERJ2RH (0402)	0.063	50	100	±0.5	100 to 100 k	(E24,E96)	±50	-55 to +155	Grade 0
ERJ2RK (0402)	0.063	50	100	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ3RB (0603)	0.1	50	100	±0.5	100 to 100 k	(E24,E96)	±50	-55 to +155	Grade 0
ERJ3RE (0603)	0.1	50	100	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ6RB (0805)	0.1	150	200	±0.5	100 to 100 k	(E24,E96)	±50	-55 to +155	Grade 0
ERJ6RE (0805)	0.1	150	200	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100	-55 to +155	Grade 0

- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Ratings

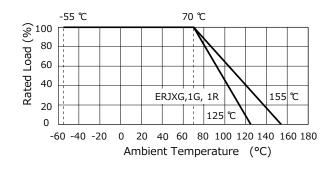
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Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resista Rang (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJXGN (01005)	0.031	15	30	±1	10 to 1 M ⁽⁴⁾	(E24,E96)	R<100 Ω : ± 300 100 Ω ≤R : ± 200	-55 to +125	-
ERJ1GN (0201)	0.05	25	50	±1	10 to 1 M ⁽⁴⁾	(E24,E96)	±200	-55 to +125	Grade 1
ERJ2RC (0402)	0.1	50	100	±1	1 to 9.76	(E24,E96)	-100 to +600	-55 to +155	Grade 0
ERJ2RK (0402)	0.1	50	100	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ3EK (0603)	0.1	75	150	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ6EN (0805)	0.125	150	200	±1	10 to 2.2 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ8EN (1206)	0.25	200	400	±1	10 to 2.2 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ14N (1210)	0.5	200	400	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ12N (1812)	0.75	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ12S (2010)	0.75	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ1TN (2512)	1	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0

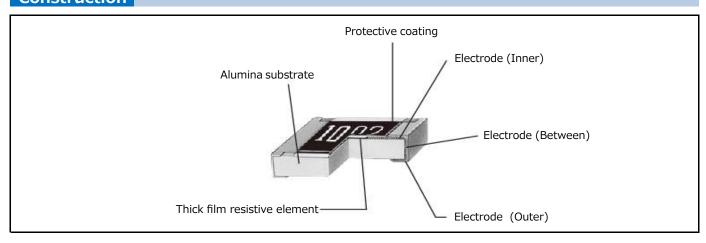
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.
- (4) Please contact us when you need a type with a resistance of less than 10 Ω .

Power Derating Curve

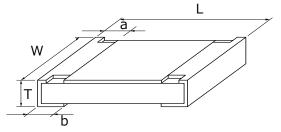
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions in mm (not to scale)



Part No.		Dimensions (mm)									
Part No.	L	W	a	b	Т	(g/1000 pcs)					
ERJXGN	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04					
ERJ1GN ERJ1R□	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15					
ERJ2R□	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8					
ERJ3R□ ERJ3EK	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2					
ERJ6R□ ERJ6EN	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4					
ERJ8EN	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10					
ERJ14N	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16					
ERJ12N	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27					
ERJ12S	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27					
ERJ1TN	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45					

Performance

• Series ERJ1R, 2R, 3R, 6R, ±0.5 %(D)

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2 %	Rated Voltage× 2.5, 5 s
Resistance to Soldering Heat	±1 %	270 °C, 10 s
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C (ERJ1R : +125 °C)(30 min.), 100 cycles
High Temperature Exposure	±1 %	+155 °C (ERJ1R: +125 °C), 1000 h
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h
Load Life in Humidity	±2 %	60 °C, 90 % to 95 %RH, Rated Voltage,
Load Life in Humidity	ERJ1R: ±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±2 % ERJ1R : ±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

• Series ERJXGN, 1GN, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN, ±1 %(F)

Test Item	Performance	Test Conditions			
rest item	Requirements ⊿R	rest conditions			
Resistance	Within Specified	20 °C			
Resistance	Tolerance	20 C			
T. C. R.	Within Specified	+25 °C/+155 °C (ERJXG,ERJ1G : +25℃/+125 °C)			
1. C. K.	T. C. R.	+23 C/+133 C (LK)AG,LK31G . +23 C/+123 C)			
Overload	±2 %	Rated Voltage× 2.5, 5 s			
Resistance to Soldering Heat	±1 %	270 °C, 10 s			
Rapid Change of Temperature	±1 %	−55 °C (30 min.)/+155 °C (ERJXG,ERJ1G : +125 °C)(30 min.),			
Rapid Change of Temperature	1 1 70	100 cycles			
High Temperature Exposure	±1 %	+155 °C (ERJXG,ERJ1G: +125 °C), 1000 h			
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h			
Load Life in Humidity	±2 %	60 °C, 90 % to 95 %RH, Rated Voltage,			
Load Life III Fluirilaity	ERJXG,1G: ±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h			
Endurance at 70 °C	±2 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			
Endurance at 70 °C	ERJXG,1G: ±3 %	70 °C, Rated Voltage, 1.5 ii ON / 0.5 ii OFF Cycle, 1000 ii			



Thin Film Chip Resistors, High Stability and Reliability Type

NEW

Thin Film Chip Resistors, High Stability and Reliability Type

ERA V (High resistance value ERA K)

Series: ERA 2V, 3V, 6V (Series: ERA 3K, 6K)



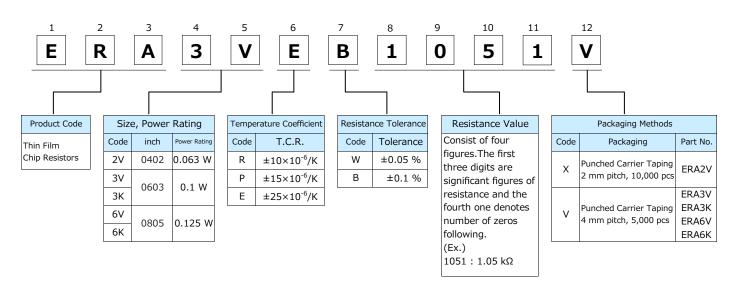
Features

- High reliability Stable at high temperature and humidity
 - (85 °C 85 %RH rated load, Category temperature range: -55 °C to +155 °C)
- High accuracy······ Low resistance tolerance and Temperature Coefficient of Resistance
- High performance… Low current noise, excellent linearity
- Anti-ESD..... Original structure for high ESD performance

(AEC-Q200-002 HBM Level 1c and above)

- Anti-sulfurated ······· Original structure for sulfurated performance
- Reference Standard····· IEC 60115-8, JIS C 5201-8, JEITA RC-2133C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



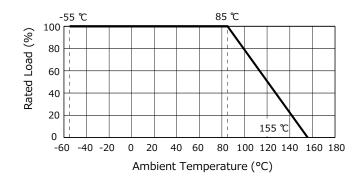


Rat	ings										
Part No. (inch size)	Power Rating at 85 °C ⁽¹⁾	Limiting Element Voltage ⁽²⁾	Maximum Overload Voltage ⁽³⁾	Part No. (detail)	Resistance Tolerance	T.C.R.	Resistance Range ⁽⁴⁾		Category Temperature Range	AEC-Q200 Grade	
	(W)	(V)	(V)		(%)	(×10 ⁻⁶ /K)	2)	2)	(℃)		
				ERA2VEB	±0.1	±25	47 to 10 k	(E24, E96)			
ERA2V	0.063	50	100	ERA2VPB	±0.1	±15					
(0402)	0.003	30	100	ERA2VRB	±0.1	±10	1 K to 10 k	(E24, E96)			
				ERA2VRW	±0.05	110					
					ERA3VEB	±0.1	±25	47 to 100 k	(E24, E96)		
ERA3V	0.1	75	75 150	ERA3VPB	±0.1	±15	1 K to 100 k	(E24, E96)	FF to 11FF	Condo 0	
(0603)	0.1	0.1 /3	130	ERA3VRB	±0.1	±10					
				ERA3VRW	±0.05	110					
ERA3K (0603)	0.1	75	150	ERA3KEB	±0.1	±25	102 K to 240 l	(E24, E96)	-55 to +155	Grade 0	
				ERA6VEB	±0.1	±25	47 to 100 k	(E24, E96)			
ERA6V	0.125	100	200	ERA6VPB	±0.1	±15					
(0805)	0.123	100	200	ERA6VRB	±0.1	±10	1 K to 100 k	K to 100 k (E24, E96)			
			ERA6VRW	±0.05	110						
ERA6K (0805)	0.125	100	200	ERA6KEB	±0.1	±25	102 K to 750 l	(E24, E96)			

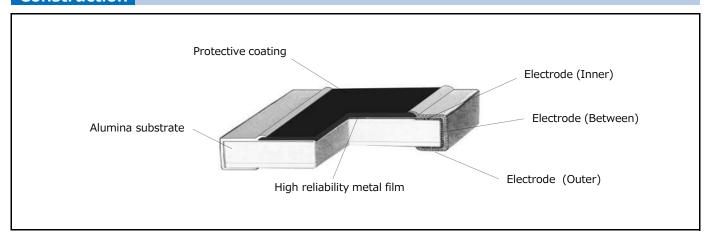
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (2.5) \times RCWV or Maximum Overload Voltage listed above, whichever less.
- (4) E192 series resistance values are also available. The E192 series has custom part numbers. Please contact us for details.

Power Derating Curve

For resistors operated in ambient temperatures above 85 °C, power rating shall be derated in accordance with the figure on the right.

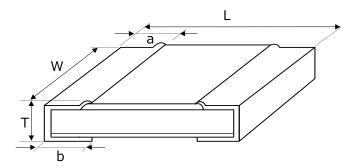


Construction





Dimensions in mm (not to scale)



Part No.		Dimensions (mm)							
Part No.	L	W	a	b	Т	(g/1000 pcs)			
ERA2V	1.00±0.05	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.35±0.05	0.6			
ERA3V, 3K	1.60±0.15	0.80±0.10	0.30±0.20	0.30±0.20	0.45±0.10	2			
ERA6V, 6K	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.55±0.10	5			

Performance

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±0.1 %	Rated Voltage× 2.5, 5 s
Resistance to Soldering Heat	±0.1 %	270 °C, 10 s
Rapid Change of Temperature	±0.1 %	-55 °C (30 min.) / +155 °C (30 min.), 1000 cycles
High Temperature Exposure	±0.1 %	+155 °C, 1000 h
Damp Heat, Steady State	±0.1 %	85 °C, 85 %RH, 1000 h
Load Life in Humidity	±0.1 %	85 °C, 85 %RH, 10 % of Rated Power ⁽¹⁾ , 1.5 h ON / 0.5 h OFF cycle , 1000 h
Endurance at 85 °C	±0.1 %	85 °C , Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Electro Static Discharge (HBM)	±0.1 % ⁽²⁾	AEC-Q200-002 : 150 pF, 2000 Ω , positive 5 times, negative 5 times ERA2V : 1.0 kV (level 1c) ERA3V(3K) : 1.5 kV (level 1c) ERA6V(6K) : 2.0 kV (level 2)

⁽¹⁾ Applied Voltage is " $\sqrt{0.1 \times \text{Power Rating} \times \text{Resistance Values}}$ ", or "Limiting Element Voltage $\times 0.316$ ", whichever less.

⁽²⁾ Depends on resistance value.

102

102



Metal Film (Thin Film) Chip Resistors, High Reliability Type

Type: ERA 1A, 2A, 3A, 6A, 8A

Features

• High reliability Stable at high temperature and humidity

(85 °C 85 %RH rated load, Category temperature range : -55 °C to +155 °C)

• High accuracy ······ Small resistance tolerance and Temperature Coefficient of Resistance

• High performance Low current noise, excellent linearity

• Reference Standard ······ IEC 60115-8, JIS C 5201-8, EIAJ RC-2133B

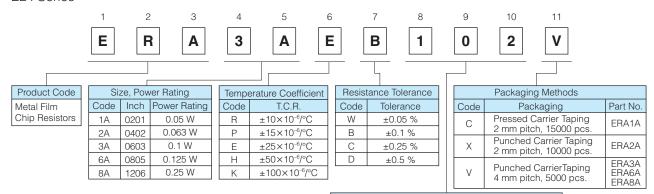
AEC-Q200 qualified

RoHS compliant

■ As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

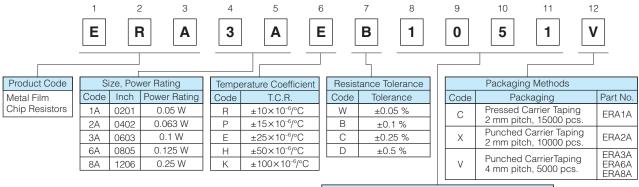
• E24 Series



Resistance Value

Consist of three figures for E24 series resistance value. The first two digits are significant figures of resistance and the third one denotes number of zeros following. (example) 102 : 1k Ω

• E96 Series and other Resistance values



Resistance Value

Consist of four figures for E96 series resistance value. The first three digits are significant figures of resistance and the fourth one denotes number of zeros following. (example) 1051 : 1.05k Ω

note: Duplicated resistance values as E24 series part numbers shall follow E24 part numbers. (apply three digit resistance value)

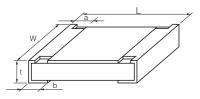
14



Metal Film (Thin Film) Chip Resistors, High Reliability Type

Construction Protective coating Electrode (Inner) Alumina substrate Electrode (Between) High reliability Electrode (Outer) metal film

Dimensions in mm (not to scale)



Part No.		Dim		Mass (Weight)		
(inch size)	L	W	а	b	t	[g/1000 pcs.]
ERA1A (0201)	0.60 ^{±0.03}	0.30 ^{±0.03}	0.15 ^{±0.05}	0.15 ^{±0.05}	0.23 ^{±0.03}	0.14
ERA2A (0402)	1.00 ^{±0.10}	0.50±8:39	0.15 ^{±0.10}	0.25 ^{±0.10}	0.35 ^{±0.05}	0.6
ERA3A (0603)						
ERA6A (0805)	2.00 ^{±0.20}	1.25 ^{±0.10}	0.40 ^{±0.25}	0.40 ^{±0.25}	0.50 ^{±0.10}	4
ERA8A (1206)	3.20 ^{±0.20}	1.60±8:95	0.50 ^{±0.25}	0.50 ^{±0.25}	0.60 ^{±0.10}	8

Ratings

Part No. (inch size)	at 95 °C	Limiting Element Voltage ⁽¹⁾ (V)	Maximum Overload Voltage ⁽²⁾ (V)	(detail)	Resistance Tolerance (%)	T.C.R. (×10 ⁻⁶ /°C)	Ran	stance ge $^{^{(3)(4)}}$	Category Temperature Range (°C)
				ERA1AEB	±0.1	±25	100 to 10)k (E24, E96)	
ERA1A	0.05	0.5	50	ERA1AEC	±0.25				_
(0201)	0.05	25	50	ERA1ARC	±0.25	10	100 to 10	k (E24, E96)	
				ERA1ARB	±0.1 ±0.05	±10	dl. to d/)L (FO4 FOC)	_
				ERA1ARW ERA2AKD	±0.05	±100)k (E24, E96)	_
				ERAZARD ERA2AED	±0.5 ±0.5	±100	10 10 46	.4 (E24, E96)	<u> </u>
				ERAZAED ERA2AEC	±0.5 ±0.25	. 05	47 to 100)k (E04 E06)	
ED A O A				ERAZAEC ERA2AEB	±0.25 ±0.1	±25	47 10 100)k (E24, E96)	
ERA2A (0402)	0.063	50	100	ERAZAEB ERA2APC					<u> </u> -
(0402)				ERA2APB	±0.25 ±0.1	±15	200 to 47	'k (E24, E96)	
				ERA2ARC	±0.1 ±0.25				_
				ERA2ARB	±0.25	±10	200 to 47	'k (E24, E96)	
-				ERA3AHD	±0.1 ±0.5	±50	10 to 46	.4 (E24, E96)	_
				ERA3AED	±0.5	±30	10 10 40	.4 (E24, E90)	-
				ERA3AEC	±0.3	±25	17 to 220)k (E24, E96)	
			150	ERA3AEB	±0.23	1 123	47 10 331	JK (L24, L90)	
ERA3A	0.1	75		ERA3APC	±0.1	±15			
(0603)	0.1	/5		ERA3APB	±0.23		470 to 100)k (E24, E96)	
				ERA3ARC	±0.1	±10			-
				ERA3ARB	±0.23		1k to 100)k (E24, E96)	-55 to +155
				ERA3ARW	±0.05		11 10 100	// (LZ4, L30)	
				ERA6AHD	±0.55	±50	10 to 46	.4 (E24, E96)	
				ERA6AED	±0.5	100	10 10 10	(LZ1, LOO)	-
				ERA6AEC	±0.25	±25	47 to 1	M (E24, E96)	
				ERA6AEB	±0.1			(== :, == =)	
ERA6A	0.125	100	200	ERA6APC	±0.25		.=	(50, 500)	-
(0805)				ERA6APB	±0.1	±15	4/0 to 100)k (E24, E96)	
				ERA6ARC	±0.25				-
				ERA6ARB	±0.1	±10	1k to 100	k (E24, E96)	
				ERA6ARW	±0.05			,	
				ERA8AHD	±0.5	±50	10 to 46	.4 (E24, E96)	1
				ERA8AED	±0.5			,	
				ERA8AEC	±0.25	±25	47 to 1	M (E24, E96)	
ED 4 0 4				ERA8AEB	±0.1			, , ,	
ERA8A (1206)	0.25	150	300	ERA8APC	±0.25		470 to 400)k (E04 E00)	1
(1200)				ERA8APB	±0.1	±15	4/U to 100)k (E24, E96)	
				ERA8ARC	±0.25	±10			
				ERA8ARB	±0.1		0 1k to 100k (E24, E96)	n)	
				ERA8ARW	±0.05				<u>' </u>

⁽¹⁾ Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Rated Power × Resistance Values, or Limiting Element Voltage listed above, whichever less.

(2) Overload (Short-time Overload) Test Voltage (SOTV) shall be determined from SOTV=2.5 × RCWV or max. Overload Voltage listed above whichever less.

(3) E192 series resistance values are also available. Please contact us for details.

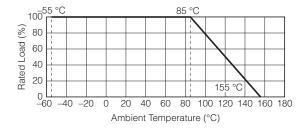
(4) Duplicated resistance values between E96, E192 and E24 series shall follow E24 Part Numbers. (apply three digit resistance value)



Metal Film (Thin Film) Chip Resistors, High Reliability Type

Power Derating Curve

For resistors operated in ambient temperatures above 85 °C, power rating shall be derated in accordance with the figure on the right.





High Precision Thick Film Chip Resistors

High Precision Thick Film Chip Resistors

1005

Series: ERJ PB3, PB6

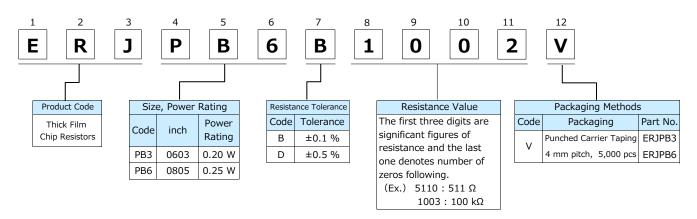
Features

- Achieve the resistance tolerance ±0.1 % with high reliability metal glaze thick film resistor
- Guarantee the temperature coefficient of Resistance $\pm 50 \times 10^{-6}$ /K in high resistance range up to 1 M Ω
- ullet High power \cdots 0.20 W : 0603 inch /1608 mm size (ERJPB3)

0.25 W: 0805 inch /2012 mm size (ERJPB6)

- Reference Standard · · · IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



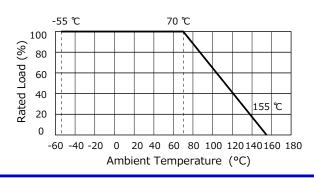
Ratings

Part No. (inch size)	Power Rating at 70 °C (1) (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJPB3 (0603)	0.20	150	200	±0.1 ±0.5	200 to 100 k	±50	-55 to +155	Grade 0
ERJPB6				±0.5 ±0.1	(E24, E96) 200 to 1 M			
(0805)	0.25	150	200	±0.5	(E24, E96)	±50	-55 to +155	Grade 0

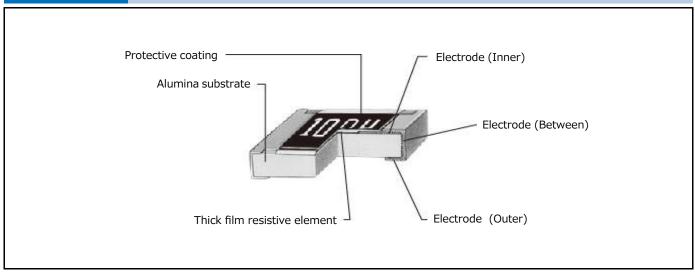
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Power Derating Curve

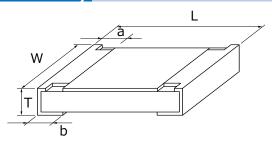
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions in mm (not to scale)



Part No.	Dimensions (mm)								
	L	W	a	b	Т	(g/1000 pcs)			
ERJPB3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2			
ERJPB6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4			

Performance

Test Item	Performance	Test Conditions
rest item	Requirements ⊿R	rest conditions
Resistance	Within Specified	20 °C
Resistance	Tolerance	20 C
T. C. R.	Within Specified	+25 °C/+125 °C
1. C. R.	T. C. R.	+25 °C/+125 °C
Overload	±0.5 %	Rated Voltage× 2.0, 5 s
Resistance to Soldering Heat	±0.5 %	270 °C, 10 s
Rapid Change of Temperature	±0.5 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles
High Temperature Exposure	±0.5 %	+155 °C, 1000 h
Damp Heat, Steady State	±0.5 %	60 °C, 90 % to 95 %RH, 1000 h
Load Life in Humidity	±0.5 %	60 °C, 90 % to 95 %RH, Rated Voltage,
Load Life III Hullilaity	±0.5 %	1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±0.5 %	70 °C, Rated Voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h



Thick Film Chip Resistors / Low Resistance Type

Thick Film Chip Resistors / Low Resistance Type

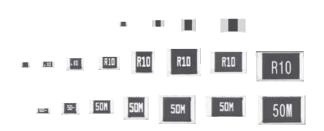
Series: ERJ 2LW, 3LW, 6LW,

ERJ 2BW, 3BW, 6BW, 8BW, 6CW, 8CW

ERJ 2B, 3B, 6D, 6B, 8B, 14B,

ERJ 3R, 6R, 8R, 14R, 12R, 12Z, 1TR

ERJ L03, L06, L08, L14, L12, L1D, L1W

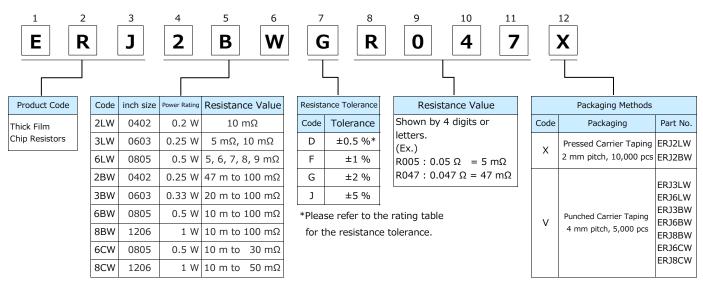


Features

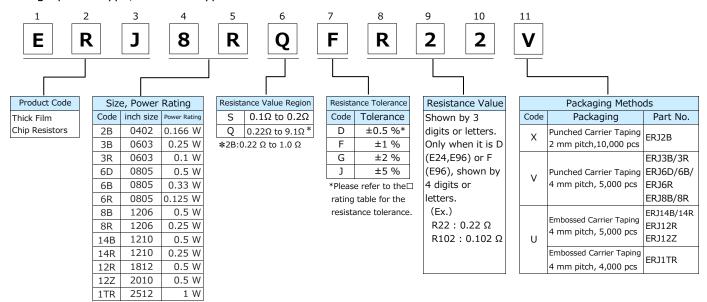
- Current Sensing resistor
- Small size and lightweight
- Realize both low-resistance & High-precision by original thick film resistive element & special electrode structure
- Suitable for both reflow and flow soldering
- Realize High-power by double-sided resistive elements structure that aimed to suppress temperature rising… ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW
- Low TCR····· ±75×10⁻⁶/K (ERJ6CW, ERJ8CW)
- ullet Low Resistance Value \cdots Thick film resistors available from 5 m Ω (ERJ3LW, 6LW)
- Reference Standard IEC 60115-8, JIS C 5201-8, JEITA RC-2144
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

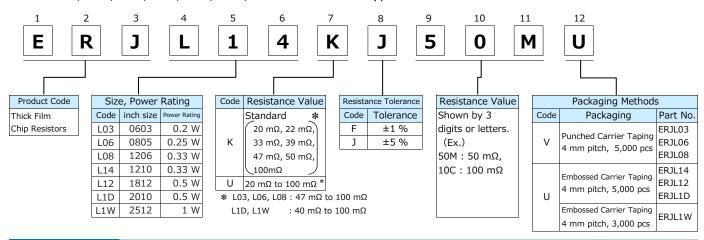
ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW
 High power (double-sided resistive elements structure) type>



• ERJ2BS/2BQ, 3BS/3BQ, 6BS/6BQ, 8BS/8BQ, 14BS/14BQ, 6D, 3R, 6R, 8R, 14R, 12R, 12Z, 1TR < High power type/Standard type>



• ERJL03, L06, L08, L14, L12, L1D, L1W <Low TCR type>



Ratings

< High power (double-sided resistive elements structure) type>

Part I (inch s		Power Rating at 70 °C ⁽¹⁾ (W)	Resistance Tolerance (%)	Resistance Range ⁽²⁾ (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJ2LW	(0402)	0.2	±1, ±2, ±5	10 m	0 to +500	-55 to +125	Grade 1
ERJ3LW	(0603)	0.25	±1, ±2, ±5	5 m 10 m	0 to +700 0 to +300	-55 to +125 -55 to +125	Grade 1
ERJ6LW	(0805)	0.5	±1, ±2, ±5	5, 6, 7, 8, 9 m	0 to +300	-55 to +125	Grade 1
ERJ2BW	(0402)	0.25	±1, ±2, ±5	47 m to 100 m (E24)	0 to +300	-55 to +155	Grade 0
ERJ3BW	(0603)	0.33	±1, ±2, ±5	20 m to 100 m (E24)	20 mΩ ≤ R < 39 mΩ:0 to +250 39 mΩ ≤ R ≤ 100 mΩ:0 to +150	-55 to +155	Grade 0
ERJ6BW	(0805)	0.5	±1, ±2, ±5	10 m to 100 m (E24)	10 mΩ ≤ R < 15 mΩ:0 to +300 15 mΩ ≤ R ≤ 100 mΩ:0 to +200	-55 to +155	Grade 0
ERJ8BW	(1206)	1	±1, ±2, ±5	10 m to 100 m(E24)	$10 \text{ m}\Omega \le R < 20 \text{ m}\Omega:0 \text{ to } +200$ $20 \text{ m}\Omega \le R < 47 \text{ m}\Omega:0 \text{ to } +150$ $47 \text{ m}\Omega \le R \le 100 \text{ m}\Omega:0 \text{ to } +100$	-55 to +155	Grade 0
ERJ6CW	(0805)	0.5	±0.5, ±1, ±2, ±5	10 m to 30 m (E24)	±75	-55 to +125	Grade 1
ERJ8CW	(1206)	1	±1, ±2, ±5	10 m to 50 m (E24)	±75	-55 to +125	Grade 1

- (1) Use it on the condition that the case temperature is below the upper category temperature.
 - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\Power Rating × Resistance Value.
 - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.
- (2) Please contact us when resistors of irregular series are needed.

Ratings

<High power type>

Part I	-	Power Rating at 70 °C ⁽¹⁾ (W)	Resistance Tolerance ⁽²⁾ (%)	Resistance Range ⁽³⁾ (Ω)		T.C.R. (×10 ⁻⁶ /K))	Category Temperature Range (℃)	AEC- Q200 Grade
ERJ2BS	(0402)	0.166	±1, ±2, ±5	0.10 to 0.20 (E24) 0	$0.10 \ \Omega \le R < 0.22 \ \Omega$: 0 to +300	-55 to +155	Grade 0
ERJ2BQ	(0402)	0.100	11, 12, 13	0.22 to 1.0 (E24) 0	$0.22 \Omega \le R \le 1.0 \Omega$: 0 to +250	55 (6 1155	Grade 0
ERJ3BS	(0603)			0.10 to 0.20 (E24) 0	$0.10 \Omega \le R < 0.22 \Omega$: 0 to +300		
ERJ3BQ	(0603)	0.25	±1, ±2, ±5	0.22 to 0.91 (E24) 0	$0.22 \Omega \le R < 1.0 \Omega$: 0 to +300	-55 to +155	Grade 0
EKJSBQ	(0003)			1.0 to 9.1 (E24)	$1.0~\Omega \le R \le ~9.1~\Omega$: ±200		
ERJ6DS	(0805)			0.10 to 0.20 (E24,	96) 0	$0.10 \Omega \le R < 0.22 \Omega$: 0 to +150		
ERJ6DQ	(0805)	0.5	±0.5, ±1, ±2, ±5	0.22 to 9.1 (E24,	96) 0	$0.22 \Omega \le R < 1.0 \Omega$: 0 to +100	-55 to +155	Grade 0
LIGODQ	(0003)			0.22 (0).1 (221,25)		$1.0 \Omega \le R \le 9.1 \Omega$: ±100		
ERJ6BS	(0805)			0.10 to 0.20 (E24) 0	$0.10 \Omega \le R < 0.22 \Omega$: 0 to +250		
ERJ6BQ	(0805)	0.33	±1, ±2, ±5	0.22 to 0.91 (E24) 0	$0.22 \Omega \le R < 1.0 \Omega$: 0 to +250	-55 to +155	Grade 0
LIGODQ	(0003)			1.0 to 9.1 (E24)	$1.0~\Omega \le R \le ~9.1~\Omega$: ±200		
ERJ8BS	(1206)			0.10 to 0.20 (E24) 0	$0.10 \ \Omega \le R < 0.22 \ \Omega$: 0 to +250		
ERJ8BQ	(1206)	0.5	±1, ±2, ±5	0.22 to 0.91 (E24) 0	$0.22 \Omega \le R < 1.0 \Omega$: 0 to +250	-55 to +155	Grade 0
LKJODQ	(1200)			1.0 to 9.1 (E24)	$1.0~\Omega \le R \le ~9.1~\Omega$: ±200		
ERJ14BS	(1210)		· · · · · · · · · · · · · · · · · · ·	0.10 to 0.20 (E24) 0	$0.10 \Omega \le R < 0.22 \Omega$: 0 to +200		
ERJ14BQ	(1210)	0.5	±1, ±2, ±5	0.22 to 0.91 (E24) 0	$0.22 \Omega \le R < 1.0 \Omega$: 0 to +200	-55 to +155	Grade 0
רעזז+מל	(1210)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega$: ±100		

- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) E96 series also have ± 0.5 %, ± 1 % line-up.
 - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\(\sqrt{Power Rating} \times \text{Resistance Value.}\)
 - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.
- (3) Please contact us when resistors of irregular series are needed.

<Standard type>

Part (inch s		Power Rating at 70 °C ⁽¹⁾ (W)	Resistance Tolerance (%)	Resistance Range ⁽²⁾ (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJ3RS	(0603)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$: 0 to +300		
ERJ3RQ	(0603)	0.1	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +300$	-55 to +155	Grade 0
LIOSINQ	(0003)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ6RS	(0805)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$: 0 to +250		
ERJ6RQ	(0805)	0.125	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$	-55 to +155	Grade 0
LIGORQ	(0003)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ8RS	(1206)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$: 0 to +250		
ERJ8RQ	(1206)	0.25	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$	-55 to +155	Grade 0
LIGUILQ	(1200)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ14RS	(1210)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$: 0 to +200		
ERJ14RQ	(1210)	0.25	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$	-55 to +155	Grade 0
LIOITING	(1210)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		
ERJ12RS	(1812)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$: 0 to +200		
ERJ12RQ	(1812)	0.5	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$	-55 to +155	Grade 0
LIVIZIVQ	(1012)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		
ERJ12ZS	(2010)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$: 0 to +200		
ERJ12ZQ	(2010)	0.5	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$	-55 to +155	Grade 0
LIVIZZQ	(2010)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		
ERJ1TRS	(2512)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$: 0 to +200		
ERJ1TRQ	(2512)	1	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$	-55 to +155	Grade 0
LIGITING	(2312)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		

- (1) Use it on the condition that the case temperature is below the upper category temperature.
 - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\(\sqrt{Power Rating} \times \text{Resistance Value.}\)
 - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.
- (2) Please contact us when resistors of irregular series are needed.

Ratings

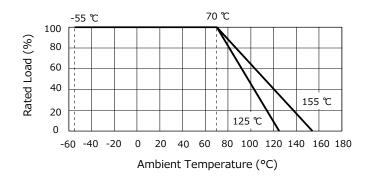
<Low TCR type>

	Part No. (inch size) Powe at 70		Resistance Tolerance (%)	Resistance Range ⁽²⁾ (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJL03	(0603)	0.2	±1, ±5	47 m to 100 m	±200	-55 to +125	Grade 1
ERJL06	(0805)	0.25	±1, ±5	47 m to 100 m	±100	-55 to +125	Grade 1
ERJL08	(1206)	0.33	±1, ±5	47 m to 100 m	±100	-55 to +125	Grade 1
ERJL14	(1210)	0.33	±1, ±5	20 m to 100 m		-55 to +125	Grade 1
ERJL12	(1812)	0.5	±1, ±5	20 m to 100 m	$R < 47 \text{ m}\Omega : \pm 300$	-55 to +125	Grade 1
ERJL1D	(2010)	0.5	±1, ±5	40 m to 100 m	$R \ge 47 \text{ m}\Omega: \pm 100$	-55 to +125	Grade 1
ERJL1W	(2512)	1	±1, ±5	40 m to 100 m		-55 to +125	Grade 1

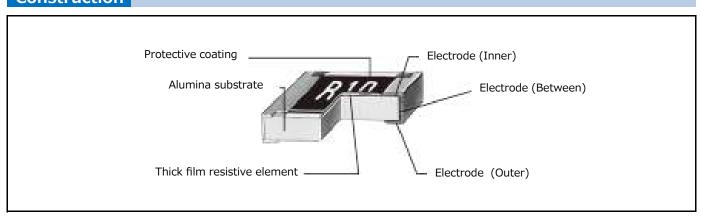
- (1) Use it on the condition that the case temperature is below the upper category temperature.
 - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\Power Rating \times Resistance Value.
 - \cdot Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) \times RCW.
- (2) Standard R.V. : 20 m Ω , 22 m Ω , 33 m Ω , 39 m Ω , 47 m Ω , 50 m Ω , 100 m Ω , Custom R.V. : Each 1 m Ω within upper range.

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

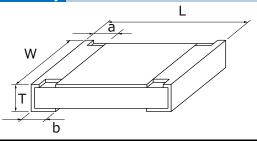


Construction





Dimensions in mm (not to scale)



Part No.			Dimensions (mm)			Mass (Weight)
rait No.	L	W	a	b	Т	(g/1000pcs)
ERJ2LW	1.00±0.10	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.40±0.05	0.8
ERJ2BW	1.00±0.10	0.50+0.10/-0.05	0.24±0.10	0.24±0.10	0.35±0.05	0.8
ERJ2B	1.00±0.10	0.50+0.10/-0.05	0.20±0.10	0.27±0.10	0.35±0.05	0.8
ERJ3LW (5 mΩ)	1.60±0.15	0.80±0.15	0.50±0.20	0.50±0.20	0.55±0.10	3
ERJ3LW (10 mΩ) ERJ3BW	1.60±0.15	0.80±0.15	0.40±0.20	0.40±0.20	0.55±0.10	3
ERJ3R ERJ3B ERJL03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2
ERJ6LW	2.00±0.20	1.25±0.20	0.63±0.20	0.63±0.20	0.70±0.10	6
ERJ6BW	2.00±0.20	1.25±0.20	0.55±0.20	0.55±0.20	0.65±0.10	6
ERJ6CW (10 to 13 mΩ)	2.05±0.20	1.30±0.20	0.60±0.20	0.60±0.20	0.65±0.10	6
ERJ6CW (15 to 30 mΩ)	2.05±0.20	1.30±0.20	0.45±0.20	0.45±0.20	0.05±0.10	
ERJ6D	2.00±0.20	1.25±0.10	0.40±0.20	0.55±0.25	0.60±0.10	5
ERJ6R ERJ6B ERJL06	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	5
ERJ8BW	3.20±0.20	1.60±0.20	1.00±0.20	1.00±0.20	0.65±0.10	13
ERJ8CW (10 to 16 mΩ)	3.20±0.20	1.60±0.20	1.10±0.20	1.10±0.20	0.65±0.10	13
ERJ8CW (18 to 50 mΩ)	3.20±0.20	1.60±0.20	0.60±0.20	0.60±0.20	0.65±0.10	13
ERJ8R ERJ8B ERJL08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10
ERJ14R ERJ14B ERJL14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16
ERJ12R ERJL12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27
ERJ12Z ERJL1D	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27
ERJ1TR	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45
ERJL1W	6.40±0.20	3.20±0.20	0.65±0.20	1.30±0.20	1.10±0.10	79



Performance

ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW
 High power (double-sided resistive elements structure) type>

Test Item	Performance Requirements ⊿R	Test Conditions					
Resistance	Within Specified	20 °C					
- Nesistance	Tolerance	20 C					
T. C. R.	Within Specified	135 90/1135 90					
1. C. K.	T. C. R.	+25 °C/+125 °C					
		ERJ6LW : Rated Voltag× 1.77, 5 s					
Overload	±2 %	ERJ8BW (R > 0.05 Ω) : Rated Voltag× 1.77, 5 s					
		Other : Rated Voltag× 2.0 , 5 s					
Resistance to Soldering Heat	±1 %	270 °C, 10 s					
David Change of Tananamahum	±1 %	-55 °C (30min.) / +155 °C (ERJ□LW, ERJ□CW : +125 °C)					
Rapid Change of Temperature	ERJ2LW: ±2 %	(30 min.), 100 cycles					
High Temperature Exposure	±1 %	+155 °C (ERJ□LW, ERJ□CW : +125 °C), 1000 h					
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h					
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage,					
Load Life in Flaminity	13 70	1.5 h ON / 0.5 h OFF cycle , 1000 h					
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h					

• ERJ2BS/2BQ, 3BS/3BQ, 6BS/6BQ, 8BS/8BQ, 14BS/14BQ, 6D, 3R, 6R, 8R, 14R, 12R, 12Z, 1TR < High power type/Standard type>

Test Item	Performance Requirements ⊿R	Test Conditions		
Resistance	Within Specified	20 °C		
	Tolerance			
T. C. R.	Within Specified	+25 °C/+125 °C		
1. C. K.	T. C. R.	+25 C/+125 C		
Overload	±2 %	Rated Voltage× 2.5 (ERJ6D : ×1.77), 5 s		
Resistance to Soldering Heat	±1 %	270 °C, 10 s		
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles		
High Temperature Exposure	±1 %	+155 °C, 1000 h		
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h		
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage,		
Load Life in Flaminity	±3 %	1.5 h ON / 0.5 h OFF cycle , 1000 h		
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		

● ERJL03, L06, L08, L14, L12, L1D, L1W < Low TCR type >

Test Item	Performance	Test Conditions			
rest item	Requirements ⊿R	rest conditions			
Resistance	Within Specified	20 °C			
Resistance	Tolerance	20 °C			
T. C. R.	Within Specified	+25 °C/+125 °C			
1. C. K.	T. C. R.	+23 C/+123 C			
Overload	±2 %	Rated Voltage× 2.5, 5 s			
Resistance to Soldering Heat	±1 %	270 °C, 10 s			
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +125 °C (30 min.), 100 cycles			
High Temperature Exposure	±1 %	+125 °C, 1000 h			
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h			
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage,			
Load Life in Flaminity	±3 %	1.5 h ON / 0.5 h OFF cycle , 1000 h			
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			



Current Sensing Resistors, Metal Plate Type

Current Sensing Resistors, Metal Plate Type

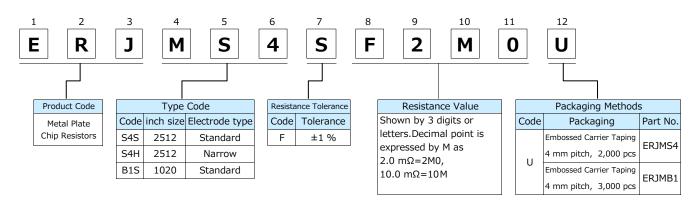


Series: ERJ MS4, MB1

Features

- Ideal for current sensing solution
- Small case size with high power
- Metal plate bonding technology. Excellent long term stability
- ullet Outer Resin with high heat dissipation. Wide temperature range (-65 $^{\circ}$ to +170 $^{\circ}$)
- AEC-Q200 compliant
- RoHS compliant
- ISO9001, ISO/TS16949 certified
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



Ratings

Part No. (inch size)	Power Rating at 70 °C (W)	Resistance Range (mΩ)	Resistance Tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	Terminal temp. upper limit (℃)	AEC-Q200 Grade
ERJMS4S (2512)	3	1, 2, 3, 4	F: ±1	±75	-65 to +170	130	Grade 0
ERJMS4H	3	5, 6	F: ±1	±75	-65 to +170	130	Grade 0
(2512)	2	7, 8, 9, 10	F: ±1	±75	-65 to +170	100	Grade 0
ERJMB1S (1020)	2	1, 2, 3, 4, 5	F: ±1	±75	-65 to +170	130	Grade 0

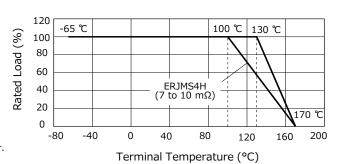
* Please contact us when resistors of irregular series are needed.

Power Derating Curve

If the terminal temperature of the resistor is more than terminal temperature upper limit value of the rated table, please reduce the rated power according to the Power Derating Curve shown in the figure on the right. <Supplemented>

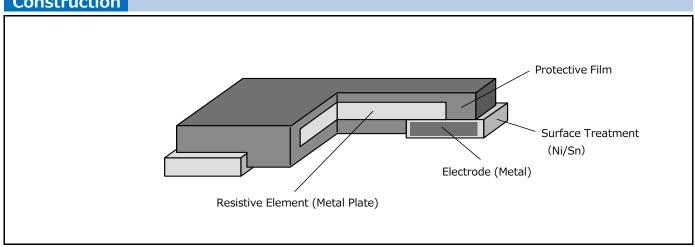
In the case of the temperature measurement of the terminal portion of the resistor, Please perform under the following conditions.

- 1) Terminal temperature measurement, please apply the temperature of the higher of either the left or right electrode upper surface of the resistor.
- 2) Please measure the temperature of the resistor in the land pattern printed of circuit board and plan to use by real conditions.



25

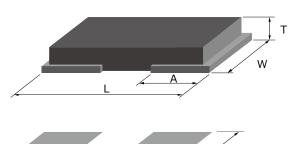
Construction

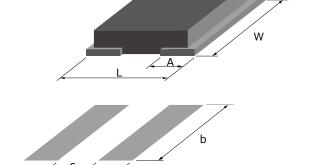


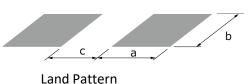
Dimensions in mm (not to scale), Recommended Land Pattern

ERJMS4S/ERJMS4H







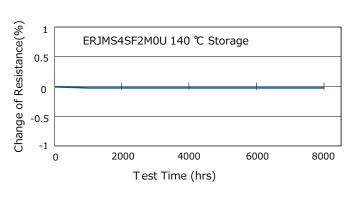


Part No.		Dimensio	Recommended Land Pattern (mm)			Mass (Weight)		
	L	W	А	Т	a	b	С	(g/1000 pcs)
ERJMS4S	6.40±0.25	3.20±0.25	2.20±0.25	1.20±0.15	2.7	3.4	2.0	120
ERJMS4H	6.40±0.25	3.20±0.25	1.25±0.25	1.20±0.15	1.7	3.4	4.0	115
ERJMB1S	2.55±0.25	5.00±0.25	0.68 +0.15/-0.20	0.90±0.15	1.15	5.5	1.1	40

Typical Temp. dependence of electrical resistance

Change of Resistance(%) 0.5 0 -0.5 -80 -60 -40 -20 0 20 40 60 80 100 120 140 160 180 Temperature (°C)

Long-term stability



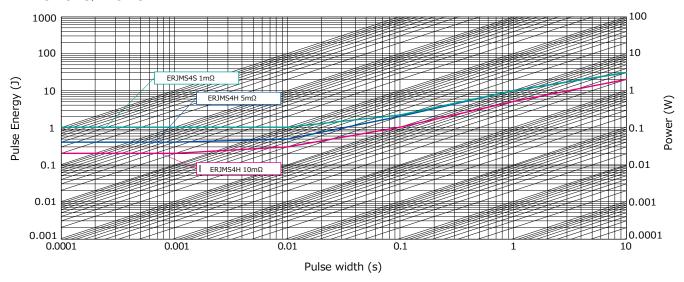
Maximum pulse energy respectively pulse power for continuous operation

Referance Data

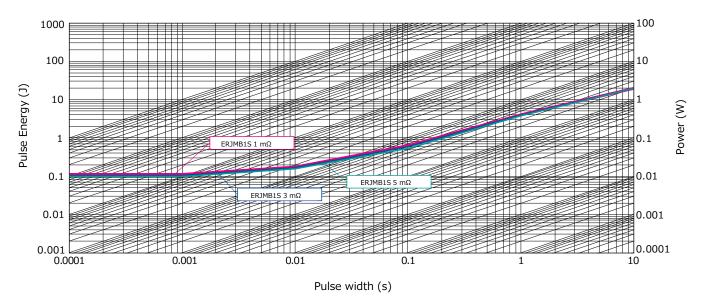
Condition: Room Temperature, OFF: 10 s, 1000 cycle, Wave form: Square

Change of Resistance = ± 1 %

ERJMS4S/ERJMS4H



• ERJMB1S



Performance (AEC-Q200)

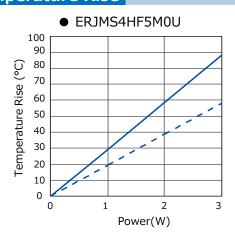
• ERJMS4S/ERJMS4H

Test Item	Performance Requirements ⊿R	Typical value ⊿R	Test Condition
Thermal Shock	±1 %	0.20 %	-55 °C / +155 °C, 1000 cycles
Overload	±0.5 %	0.10 %	Rated Power× 3, 5 s
Solderability	> 95% coverage	> 95% coverage	245 °C, 3 s
Resistance to Solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low Temperature Storage and Operation	±0.5 %	0.03 %	-65 °C, 24 h
Resistance to Soldering Heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 °C, 10 s)
Moisture Resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High Frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 °C, Rated Power, 2000 h
Storage Life at Elevated Temperature	±1 %	0.30 %	170 °C, 2000 h
High Temperature Characteristics	±0.5 %	0.05 %	140 °C, 2000 h
Frequency Characteristics	< 5 nH	< 2 nH	Inductance

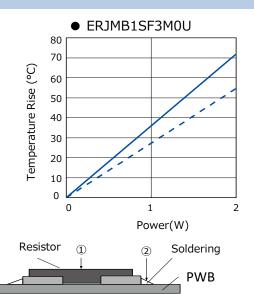
• ERJMB1

Test Item	Performance Requirements ⊿R	Typical value ⊿R	Test Condition
Thermal Shock	±1 %	0.30 %	-55 °C / +155 °C, 1000 cycles
Overload	±1 %	0.30 %	Rated Power× 2.5, 5 s
Solderability	> 95% coverage	> 95% coverage	245 °C, 3 s
Resistance to Solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low Temperature Storage and Operation	±0.5 %	0.03 %	−65 °C, 24 h
Resistance to Soldering Heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 °C, 10 s)
Moisture Resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High Frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 °C, Rated Power, 2000 h
Storage Life at Elevated Temperature	±1 %	0.30 %	170 °C, 2000 h
High Temperature Characteristics	±0.5 %	0.05 %	140 °C, 2000 h
Frequency Characteristics	< 5 nH	< 2 nH	Inductance

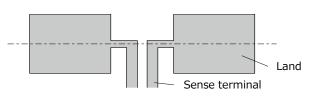
Temperature Rise



Condition>
 Base material : FR-4 (t 1.6 mm)
 Copper Thickness : 70 µm, Two layer



Sense terminal-Layout







High Power Chip Resistors / Wide Terminal Type







Series: ERJ A1, B1, B2, B3

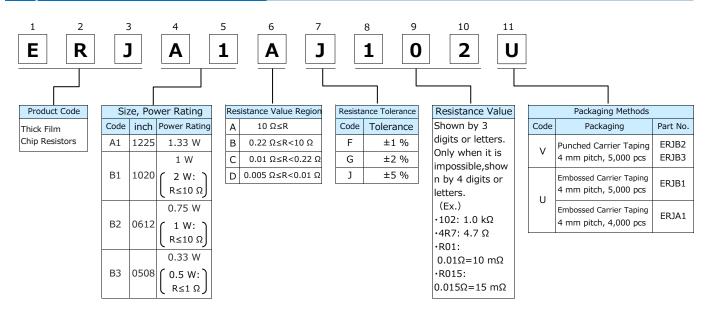
Features

- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended Applications

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

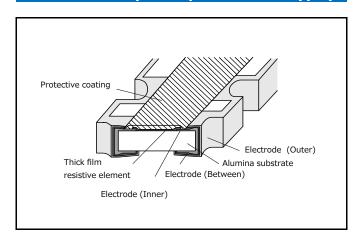


Ratings

Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resistand Range (Ω)	ce	T.C.R. (×10 ⁻⁶ /k		Category Temperature Range (℃)	AEC- Q200 Grade		
				±1	100 m to 10 k	(E24)	±100					
ERJA1 (1225)	1.33	200	400	±2, ±5	10 m to 10 k	(E24)	R<100mΩ 100mΩ≤R	: ±350 : ±200		Grade 0		
·							R< 22mΩ	: 0 to +350				
				±1	10 m to 10 k	(E24)	22mΩ ≤R< 47mΩ	: 0 to +200				
ED1D1	1			±1	10 III to 10 K	(E24)	47mΩ ≤R<100mΩ	: 0 to +150				
ERJB1 (1020)	$1 \\ 2(R \le 10 \Omega)$	200	400				100mΩ ≤R	: ±100		Grade 0		
(1020)					R< 22mΩ	: 0 to +350						
			±2, ±5	10 m to 10 k	(E24)	22mΩ ≤R<100mΩ	: 0 to +200					
									100mΩ ≤R	: ±200		
				±1			R< 22mΩ	: 0 to +300				
							22mΩ ≤R< 47mΩ	: 0 to +200				
					10 m to 1 M	(E24)	47mΩ ≤R<100mΩ	: 0 to +150	-55 to +155			
								100mΩ ≤R<220mΩ	: 0 to +100	33 to 1133		
ERJB2	0.75	200	400				220mΩ ≤R	: ±100		Grade 0		
(0612)	$1(R \le 10 \Omega)$	200	400	±2	10 m to 1 M	(E24)	R< 22mΩ	: 0 to +300		Grade 0		
					5 m, 6 m,		22mΩ ≤R< 47mΩ	: 0 to +200				
				±5	7 m, 8 m,	(E24)	47mΩ ≤R<100mΩ	: 0 to +150				
					9 m,		100mΩ ≤R<220mΩ	: 0 to +200				
					10 m to 1 M		220mΩ ≤R	: ±200				
							R< 47mΩ	: 0 to +300				
				±1	20 m to 10	(E24)	47mΩ ≤R< 1Ω	: 0 to +200				
ERJB3	0.33	150	200				1Ω ≤R	: ±100		Grade 0		
(0508)	$0.5(R \le 1 \Omega)$	130					R< 47mΩ	: 0 to +300				
				±2, ±5	20 m to 10	(E24)	47mΩ ≤R< 1Ω	: 0 to +200				
							1Ω ≤R	: ±200				

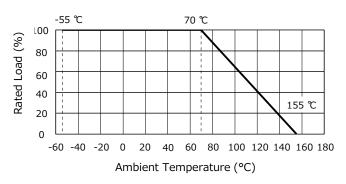
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= \sqrt{Power} Rating \times Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Construction (Example : ERJA1 type)

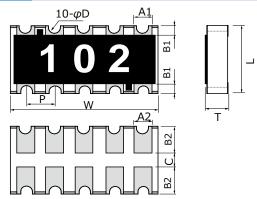


Power Derating Curve

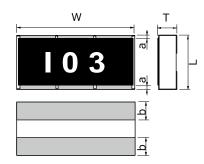
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.



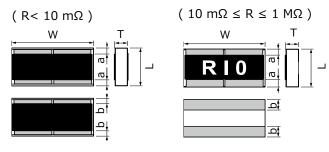
Dimensions in mm (not to scale)



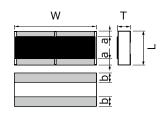
Part No.	Dimensions (mm)							
Part No.	L	W	Т	A_1	B ₁	(g/1000 pcs)		
	3.20±0.20	6.40±0.20	0.55±0.10	0.70±0.20	0.45±0.20			
ERJA1	A ₂	B ₂	Р	φD	С	40		
	0.70±0.20	1.25±0.15	1.27±0.10	0.30+0.10/-0.20	0.4 min.			



Part No.		Dimensions (mm)							
Part No.	L	W	T	a	b	(g/1000 pcs)			
ERJB1	2.50±0.20	5.00±0.20	0.55±0.20	0.25±0.20	0.90±0.20	27			



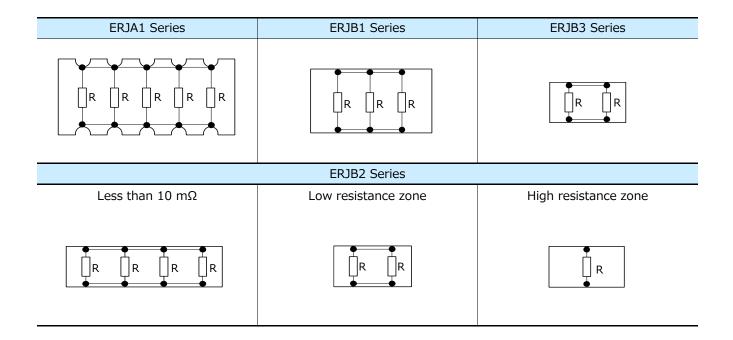
Part No.		Dimensions (mm)						
ERJB2	L	W	Т	а	b	(g/1000 pcs)		
5 mΩ≤R< 10 mΩ			0.65±0.15	0.30±0.20	0.30±0.20			
10 mΩ≤R<220 mΩ	1.60±0.15	3.20±0.20	0.55±0.15	0.30±0.20	0.50±0.20	11		
220 mΩ≤R≤ 1 MΩ			0.55±0.15	0.25±0.20	0.50±0.20			



Part No.	Dimensions (mm)						
Part No.	L	W	T	a	b	(g/1000 pcs)	
ERJB3	1.25±0.10	2.00±0.15	0.50±0.10	0.25±0.20	0.40±0.20	4.8	



Circuit Configuration



Performance

Test Item	Performance Requirements ⊿R	Test Conditions			
Resistance	Within Specified Tolerance	20 °C			
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C			
Overload	±2 %	$ \begin{array}{llllllllllllllllllllllllllllllllllll$			
Resistance to Soldering Heat	±1 %	270 °C, 10 s			
Rapid Change of Temperature	±2 %	-55 °C (30 min.) / +125 °C(30 min.), 1000 cycles			
High Temperature Exposure	±1 %	+155 °C, 1000 h			
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h			
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			



Low TCR High Power Chip Resistors / Wide Terminal Type

.010

.010

Series: ERJ D1, D2

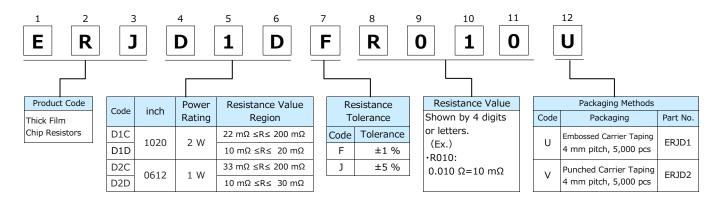
Features

- ullet Achieved High power and low TCR ($\pm 100 \times 10^{-6}$ /K) using wide terminal electrode structure and original material
- Suitable for small size/high power current detection (Low TCR enables high accuracy of current detection)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended Applications

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



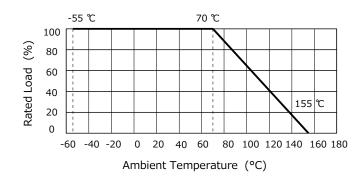
Ratings

Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJD1 (1020)	2	±1, ±5	10 m to 200 m (E24)	±100	-55 to +155	Grade 0
ERJD2 (0612)	1	±1, ±5	10 m to 200 m (E24)	±100		

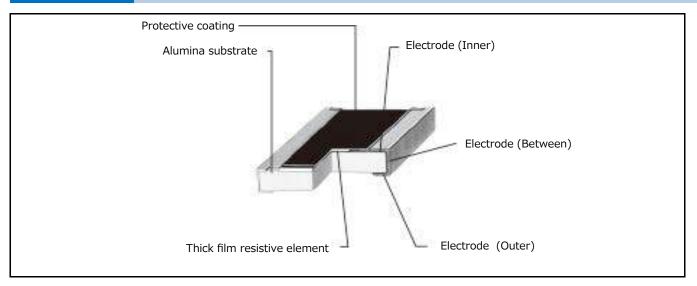
- (1) Use it on the condition that the case temperature is below the upper category temperature.
 - Please contact us when resistors of irregular series are needed.
 - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\(\sqrt{Power Rating} \times \text{Resistance Value.}\)
 - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV.

Power Derating Curve

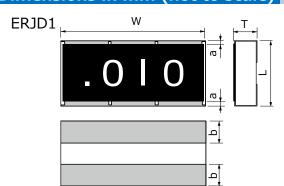
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

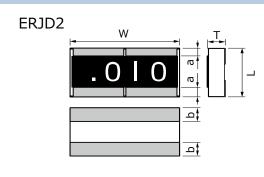


Construction



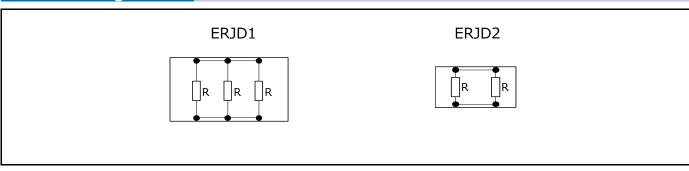
Dimensions in mm (not to scale)





Part No.	Dimensions (mm)							
rait No.	L	W	Т	a	b	(g/1000 pcs)		
ERJD1	2.50±0.20	5.00±0.20	0.60±0.20	0.30±0.20	0.90±0.20	27		
ERJD2	1.60±0.15	3.20±0.20	0.65±0.15	0.30±0.20	0.50±0.20	11		

Circuit Configuration





Test Item	Performance Requirements ⊿R	Test Conditions		
Resistance Within Speci		20 °C		
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C		
Overload	±2 %	Rated Voltag× 2.0 , 5 s		
Resistance to Soldering Heat ±1 %		270 °C, 10 s		
Rapid Change of Temperature	±2 %	-55 °C (30 min.) / +125 °C(30 min.), 1000 cycles		
High Temperature Exposure	±1 %	+155 °C, 1000 h		
Damp Heat, Steady State ±1 %		60 °C, 90 % to 95 %RH, 1000 h		
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		



Anti-Surge Thick Film Chip Resistors

Anti-Surge Thick Film Chip Resistors

102 102 102

Series: ERJ PA2, P03, PA3, P06, P08, P14

Features

- ESD surge characteristics superior to standard metal film resistors
- High reliability...Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power… 0.20 W: 0402 inch / 1005 mm size (ERJPA2), 0603 inch / 1608 mm size (ERJP03)

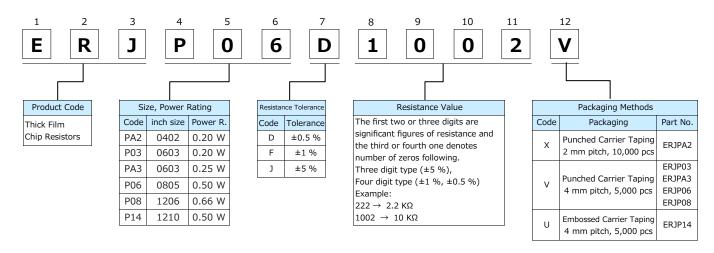
0.25 W: 0603 inch / 1608 mm size (ERJPA3)

0.50 W: 0805 inch / 2012 mm size (ERJP06), 1210 inch / 3225 mm size (ERJP14)

0.66 W: 1206 inch / 3216 mm size (ERJP08)

- Reference Standard · · · IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



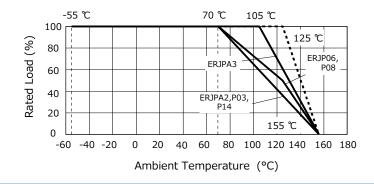
Ratings

Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Ra	Resistance Range (Ω)		T.C.R. (×10 ⁻⁶ /K)		AEC-Q200 Grade
ERJPA2	0.20	50	100	±0.5, ±1	10 to 1 M	(E24, E96)	±	100		Grade 1
(0402)	0.20	30	100	±5	10 to 1 M	(E24)	±	200		Grade 1
				±0.5	10 to 1 M	(E24, E96)	±:	150		
ERJP03	0.20	150	200	±1	10 to 1 M	(E24, E96)	±	200		Grade 0
(0603)	0.20	130	200	±5	1 to 1 M	(E24)	R<10Ω	: -150 to +400		Grade 0
					1 10 1 14	(L24)	10Ω≤R	: ±200		
ERJPA3	0.25	150	200	±0.5, ±1	10 to 1 M	(E24, E96)	±:	100		Grade 0
(0603)	(105 ℃)	130	200	±5	1 to 1.5 M (E24)		±200			Grade 0
				TUE T 1	10 to 1 M	(E24, E96)	R<33Ω	: ±300		
ED1006				10.5, 11	10 to 1 M	(624, 690)	33Ω≤R	: ±100	-55 ~ +155	
ERJP06 (0805)	0.50	400	600				R<10Ω	: -100 to +600		Grade 0
(0003)				±5	1 to 3.3 M	(E24)	10Ω≤R<33Ω	: ±300		
							33Ω≤R	: ±200		
ED 1000				±0.5, ±1	10 to 1 M	(E24, E96)	±	100		
ERJP08 (1206)	0.66	500	1000	±5	1 to 10 M	(E24)	R<10Ω	: -100 to +600		Grade 0
(1200)				Ξ3	1 to 10 M	(E24)	10Ω≤R	: ±200		
ED 104 4				±0.5, ±1	10 to 1 M	(E24, E96)	±	100		
ERJP14 (1210)	0.50	200	400	±5	1 to 1 M	(E24)	R<10Ω	: -100 to +600		Grade 0
(1210)				π 5	1 to 1 M	(E24)	10Ω≤R	: ±200		

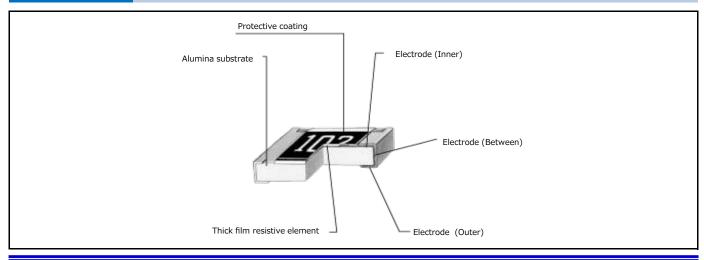
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) \times RCWV or Maximum Overload Voltage listed above, whichever less.

Power Derating Curve

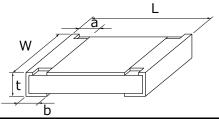
For resistors operated in rated temperatures above 70 °C or 105 °C, power rating shall be derated in accordance with the figure on the right. * When the temperature of ERJP14 is 155 °C or less, the derating start temperature can be changed to 125 °C. (See the dotted line)



Construction

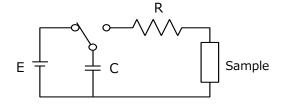


Dimensions in mm (not to scale)



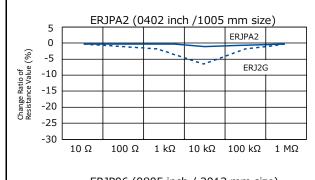
Part No.		Dimensions (mm)							
rarervor	L	W	а	b	t	(g/1000 pcs)			
ERJPA2	1.00±0.05	0.50±0.05	0.20±0.15	0.25±0.05	0.35±0.05	0.8			
ERJP03	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.30±0.15	0.45±0.10	2			
ERJPA3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2			
ERJP06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4			
ERJP08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10			
ERJP14	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16			

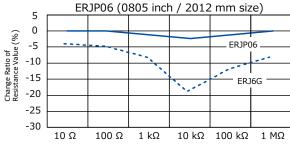
ESD Characteristic

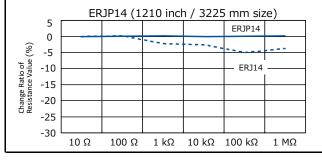


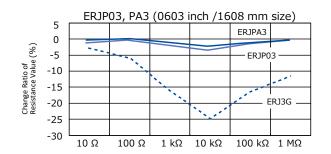
Size (inch)	0402	0603, 0805, 1206, 1210
R	1.5 kΩ	R=0 Ω(≤1.5 kΩ) / 150 Ω(>1.5 kΩ)
С	100 pF	150 pF
Е	±1 kV	±3 kV

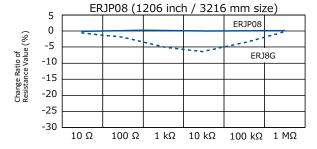
Anti-Surge Thick Film Chip Resistors (ERJP Series)
Thick Film Chip Resistors (ERJ Series)











%This data is for reference purposes.
Please check with the actual equipment before use.



Anti-Surge Thick Film Chip Resistors

Test Item	Performance Requirements ∠R	Test Conditions		
Resistance	Within Specified Tolerance	20 °C		
T. C. R.	Within Specified T. C. R.	+25 °C/+155 °C (ERJPA2 : +125 °C)		
	12.00	ERJP06 : Rated Voltag× 1.77, 5 s		
Overload	$\pm 2\%$ Only when it is ERJP03 (D), P14 (D): $\pm 0.5\%$	ERJPA2, ERJPA3, ERJP08: Rated Voltag× 2.0 , 5 s		
	Only When it is Elon 03 (b), 114 (b) . 10.3 %	ERJP03, ERJP14 : Rated Voltag× 2.5 , 5 s		
Resistance to	D: ±0.5 %, F, J: ±1 %	270 °C, 10 s		
Soldering Heat	2 1 = 0.0 75/ 1/ 3 1 = 1 75	, and the second		
Rapid Change of	±1 %	-55 °C (30min.) / +155 °C (ERJPA2 : +125 °C) (30min.),		
Temperature	-1 /3	100 cycles		
High Temperature	±1 %	+155 °C, 1000 h		
Exposure	-1 /0	1133 C, 1000 II		
Damp Heat, Steady	±1 %	60 °C, 90 % to 95 %RH, 1000 h		
State	21 70	00 C, 90 % to 93 ///(1, 1000 11		
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage,		
Load Life in Fidinialty	Only when it is ERJP03 (D), P14 (D): ±1 %	1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70 °C	±3 %	70 °C (ERJPA3 : +105 °C), Rated Voltage,		
(ERJPA3 : 105 °C)	Only when it is ERJP03 (D), P14 (D) : ± 1 %	1.5 h ON / 0.5 h OFF cycle, 1000 h		



Anti-Pulse Thick Film Chip Resistors

Anti-Pulse Thick Film Chip Resistors









Series: ERJ T06, T08, T14

ERJ T14L

Features

- Anti-Pulse characteristics
 High pulse characteristics achieved by the optimized trimming specifications (ERJT06, T08, T14)
- Further high pulse characteristics achieved by trimming-less specifications (ERJT14L)
- High reliability ····· Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power ······· 0.25 W: 0805 inch /2012 mm size (ERJT06)

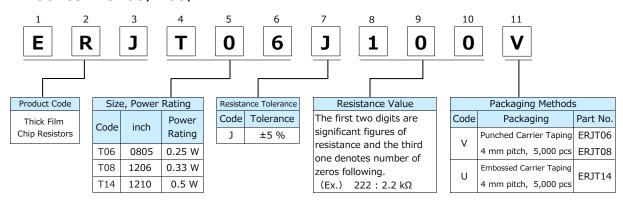
0.33 W: 1206 inch /3216 mm size (ERJT08)

0.50 W: 1210 inch /3225 mm size (ERJT14, ERJT14L)

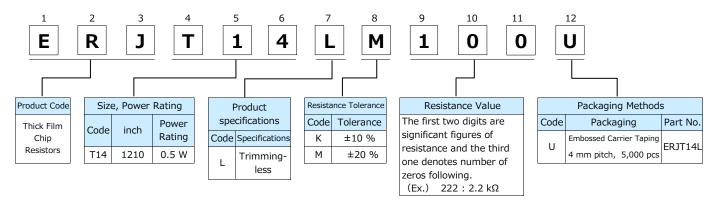
- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

Series ERJT06, T08, T14



Series ERJT14L



* Please contact us for 0805 (inch) and 1206 (inch) size trimming-less types.

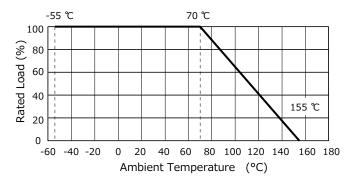
Ratings

Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJT06 (0805)	0.25	150	200	±5	1 to 1 M (E24)	R<10 Ω : -100 to +600 10 Ω≤R<33 Ω : ±300 33 Ω≤R : ±200	-55 to +155	Grade 0
ERJT08 (1206)	0.33	200	400	±5	1 to 1 M (E24)	R<10 Ω : -100 to +600 10 Ω≤R : \pm 200	-55 to +155	Grade 0
ERJT14 (1210)	0.50	200	400	±5	1 to 1 M (E24)	R<10 Ω : -100 to +600 10 Ω≤R : \pm 200	-55 to +155	Grade 0
ERJT14L (1210)	0.50	200	400	±10 ±20	1 to 1 M (E12)	R<10 Ω : -100 to +600 10 Ω≤R : \pm 200	-55 to +155	Grade 0

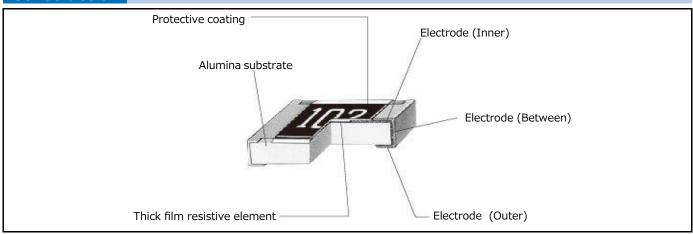
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Power Derating Curve

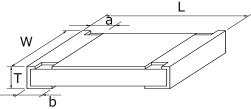
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



Construction



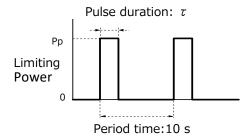
Dimensions in mm (not to scale)



Dart No.	Dimensions (mm)							
Part No.	L	W	a	b	Т	(g/1000 pcs)		
ERJT06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4		
ERJT08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10		
ERJT14 ERJT14L	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16		

Limiting Power Curve

• In rush pulse Characteristic



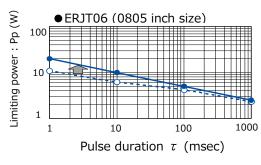
Test cycle: 1000 cycles

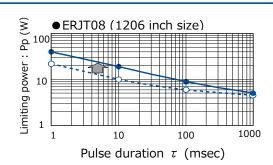
Spec : Resistance value = within $\pm 5 \%$

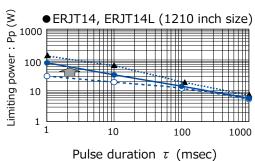
▲: Anti-Pulse Thick Film Chip Resistors (Series ERJT14L)

• : Anti-Pulse Thick Film Chip Resistors (Series ERJT)

 \bigcirc : Thick Film Chip Resistors (Series ERJ : 1 Ω)







- **This data is for reference purposes.
 Please check with the actual equipment before use.
- Please contact us for 0805 (inch) and 1206 (inch) size trimming-less types.

Test Item	Performance Requirements ⊿R	Test Conditions			
Resistance	Within Specified Tolerance	20 °C			
T. C. R.	Within Specified T. C. R.	+25 °C/+155 °C			
Overload	±2 %	Rated Voltage× 2.5, 5 s			
Resistance to \$\text{\$\pm\$1 %}\$		270 °C±3 °C, 10 s ±1 s			
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles			
High Temperature Exposure	±1 %	+155 °C, 1000 h			
Damp Heat, Steady State	±1 %	60 °C ±2 °C, 90 % to 95 %RH, 1000 h			
Load Life in Humidity	±3 %	60 °C ±2 °C, 90 % to 95 %RH, Rated Voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h			
Endurance at 70 °C	±3 %	70 °C ±2 °C, Rated Voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h			



Anti-Sulfurated Thick Film Chip Resistors

Anti-Sulfurated Thick Film Chip Resistors

102 102 102

ERJ S (Au-based inner electrode type)

Series: ERJ S02, S03, S06, S08, S14, S12, S1D, S1T

ERJ U (Ag-Pd-based inner electrode type)

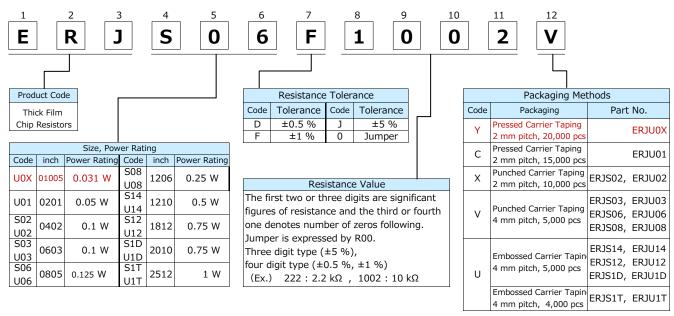
Series: ERJ UOX, U01, U02, U03, U06, U08, U14, U12, U1D, U1T, U6S, U6Q

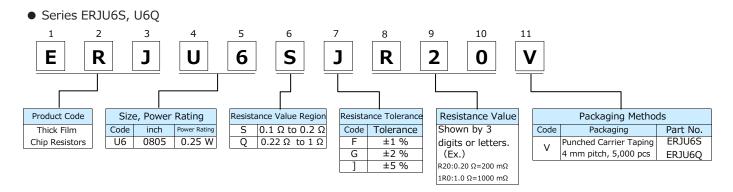
Features

- High resistance to sulfurization achieved by adopting an Au-based inner electrode (Series ERJS) and Ag-Pd-based inner electrode (Series ERJU)
- High reliability...Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- ullet Low Resistance type ... Series ERJU6S, U6Q : 0.1 Ω to 1 Ω
- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant (except ERJU0X, ERJU01)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

Series ERJS02 to ERJS1T, ERJU0X to ERJU1T





Rati	Ratings								
Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Ra	stance nge Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJU0X (01005)	0.031	15	30	±1 ±5	10 to 1 M	(E24, E96)	R<10 Ω : -100 to +600 10 Ω≤R<100 Ω : ±300 100 Ω≤R : ±200	-55 to +125	-
ERJU01 (0201)	0.05	25	50	±1 ±5	10 to 1 M	,	R<10 Ω: -100 to +600	-55 to +125	_
ERJS02 ERJU02	0.1	50	100	±0.5, ±1 ±5	1 to 1 M	(E24, E96)	10 Ω to 1 M Ω : ±200 1 M Ω <r :<="" td=""><td>-55 to +155</td><td>Grade 0</td></r>	-55 to +155	Grade 0
(0402) ERJS03 ERJU03	0.1	75	150	±0.5, ±1	1 to 1 M	(E24, E96) (E24)	-400 to +150	-55 to +155	Grade 0
(0603) ERJS06 ERJU06	0.125	150	200	±0.5, ±1 ±5	1 to 1 M	(E24, E96) (E24)		-55 to +155	Grade 0
(0805) ERJS08 ERJU08	0.25	200	400	±0.5, ±1 ±5	1 to 1 M	(E24, E96) (E24)	R<10 Ω: -100 to +600	-55 to +155	Grade 0
(1206) ERJS14 ERJU14 (1210)	0.5	200	400	±0.5, ±1 ±5	1 to 1 M 1 to 10 M		10 Ω to 1 MΩ: ±200 (± 5 %)	-55 to +155	Grade 0
ERJS12 ERJU12 (1812)	0.75	200	500	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	±100 (±0.5 %, ±1 %)	-55 to +155	Grade 0
ERJS1D ERJU1D (2010)	0.75	200	500	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)		-55 to +155	Grade 0
ERJS1T ERJU1T (2512)	1.0	200	500	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)		-55 to +155	Grade 0

(1) Use it on the condition that the case temperature is below the upper category temperature.

(2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= $\sqrt{\text{Power Rating}} \times \text{Resistance Value}$, or Limiting Element Voltage listed above, whichever less.

(3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

[Low Resistance type]

Ī	Part No.	Power Rating Resistance		Resistance		T.C.R.	Category Temperature	AEC-
		at 70 °C ⁽¹⁾	Tolerance	Range	е	_	Range	Q200
	(inch size)	(W)	(%)	(Ω)		(×10 ⁻⁶ /K)	(℃)	Grade
	ERJU6S (2012)	0.25	±1, ±2, ±5	0.1 to 0.2	(E24)	0 to +150	-55 to +155	Grade 0
-	ERJU6Q (2012)	0.25	±1, ±2, ±5	0.22 to 1	(E24)	0 (0 +150	-55 (0 +155	Grade 0

(1) Use it on the condition that the case temperature is below the upper category temperature.

- Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= $\sqrt{\text{Power Rating} \times \text{Resistance Value.}}$
- · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

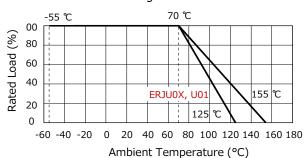
[For Jumper]

tror Jumpe	rj –			
Part No.	Resistance(Ω)	Rated Current(A)	Maximum Overload Current (A) ⁽¹⁾	
ERJU0X		0.5	1	
ERJU01		0.5	1	
ERJS02 ERJU02		1	2	
ERJS03 ERJU03		_	_	
ERJS06 ERJU06	100 mΩ or less			
ERJS08 ERJU08	100 11132 01 1033			
ERJS14 ERJU14		2	4	
ERJS12 ERJU12		2	7	
ERJS1D ERJU1D				
ERJS1T ERJU1T				

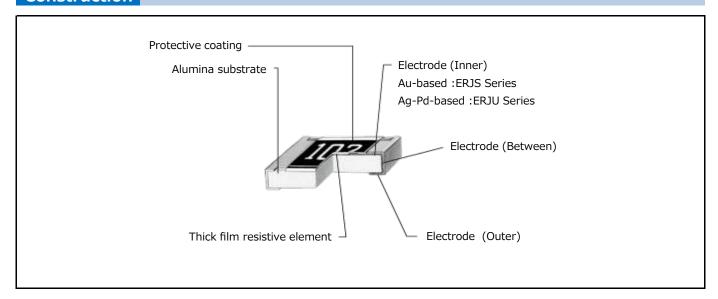
(1) Overload test current

Power Derating Curve

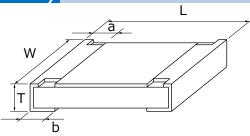
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.



Construction



Dimensions in mm (not to scale)



Part No.	Dimensions (mm)								
Part No.	L	W	a	b	Т	(g/1000 pcs)			
ERJU0X	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04			
ERJU01	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15			
ERJS02 ERJU02	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.10	0.35±0.05	0.8			
ERJS03 ERJU03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2			
ERJS06 ERJU06	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4			
ERJU6□	2.00±0.20	1.25±0.10	0.45±0.20	0.45±0.20	0.55±0.10	6			
ERJS08 ERJU08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10			
ERJS14 ERJU14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16			
ERJS12 ERJU12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27			
ERJS1D ERJU1D	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27			
ERJS1T ERJU1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45			

Performance

• Series ERJS02 to ERJS1T, ERJU0X to ERJU1T

Test Item	Performance Re	equirements ⊿R	Test Conditions
rest item	Resistor type	Jumper type	rest conditions
Resistance	Within Specified	100 mΩ or less	20 °C
Resistance	Tolerance	100 11132 01 1655	20 °C
T. C. R.	Within Specified	200 mΩ or less	+25 °C/+155 °C (ERJU0X,U01 : +25 °C/+125 °C)
	T. C. R.	200 1132 01 1033	+23 C/+133 C (LIGOOX,001: +23 C/+123 C)
Overload	±2 %	100 mΩ or less	Rated Voltage× 2.5, 5 s
Overload	12 /0	100 11132 01 1633	Jumper type: Max. Overload Current, 5 s
Resistance to	±1 %	100 mΩ or less	270 °C, 10 s
Soldering Heat	11 70	100 11132 01 1655	270 °C, 10 S
Rapid Change of	±1 %	100 mΩ or less	-55 °C (30min.)/+155 °C (ERJU0X,U01 : +125 °C)
Temperature	<u> </u>	100 1112 01 1622	(30min.), 100 cycles
High Temperature	±1 %	100 mΩ or less	11EE 9C (ED1HOV HO1 + 113E 9C) 1000 h
Exposure	11 70	100 11132 01 1655	+155 °C (ERJU0X,U01 : +125 °C), 1000 h
Damp Heat, Steady	±1 %	100 mΩ or less	60 °C, 90 % to 95 %RH, 1000 h
State	<u> </u>	100 11132 01 1033	00 C, 90 % to 93 %KH, 1000 H
Load Life in Humidity	±3 %	100 mΩ or less	60 °C, 90 % to 95 %RH, Rated Voltage (Jumper type :
Load Life in Fluinidity	±5 /0	100 11132 01 1655	Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 0C	12.0/	100 0	70 °C, Rated Voltage (Jumper type :Rated Current),
Endurance at 70 °C	±3 %	100 m Ω or less	1.5 h ON / 0.5 h OFF cycle, 1000 h

• Series ERJU6S, U6Q

Test Item	Performance Requirements ⊿R	Test Conditions			
Resistance	Within Specified	20 °C			
Resistance	Tolerance	20 °C			
T. C. R.	Within Specified	125 00/1125 00			
1. C. N.	T. C. R.	+25 °C/+125 °C			
Overload	±1 %	Rated Voltage× 2.5, 5 s			
Resistance to	±1 %	270.9C 10.c			
Soldering Heat	±1 70	270 °C, 10 s			
Rapid Change of	±1 %	-55 °C (30 min.) / +125 °C(30min.), 100 cycles			
Temperature	±1 /0				
High Temperature	±1 %	+155 °C, 1000 h			
Exposure	±1 /0	+133 C, 1000 H			
Damp Heat, Steady	±1 %	60 °C, 90 % to 95 %RH, 1000 h			
State	-1 /0	00 C, 90 % to 95 % tt 1, 1000 ff			
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage,			
Load Life in Humbley	±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h			
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			





Anti-Sulfurated Thick Film Chip Resistors / Precision Type







Series: ERJ U2R, U3R, U6R

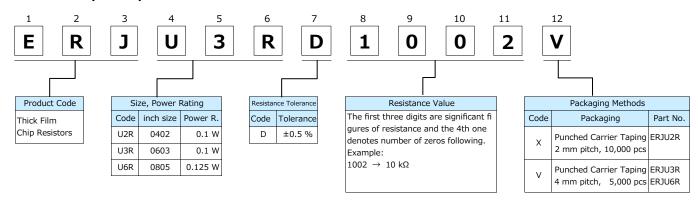
(Ag-Pd-based inner electrode type)

Features

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode.
- ◆ High precision ··· Resistance tolerance : ±0.5 %, TCR : ±50 ×10⁻⁶/K
- High reliability ··· Metal glaze thick film resistive element and three layers of electrodes.
- Suitable for both reflow and flow soldering.
- Reference Standard · · · IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

• ERJU2R, U3R, U6R Series



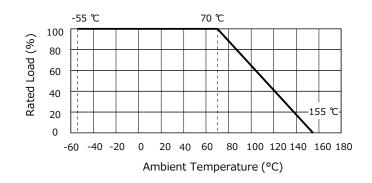
Ratings

	Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
	ERJU2R (0402)	0.1	50	100	±0.5	100 to 100 k (E24, E96)		-55 to +155	Grade 0
•	ERJU3R (0603)	0.1	50	100	±0.5	100 to 100 k (E24, E96)	±50	-55 to +155	Grade 0
•	ERJU6R (0805)	0.125	150	200	±0.5	100 to 100 k (E24, E96)		-55 to +155	Grade 0

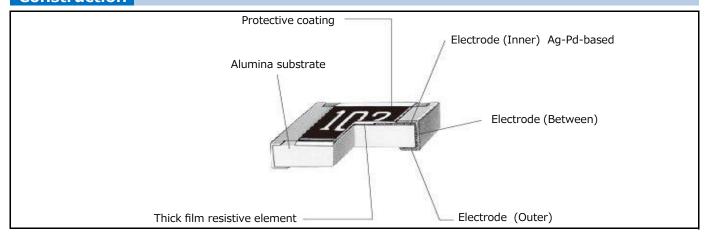
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Power Derating Curve

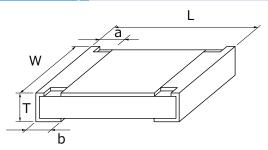
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions in mm (not to scale)



Part No.	Dimensions (mm)								
	L	W	a	b	Т	(g/1000 pcs)			
ERJU2R	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.10	0.35±0.05	0.8			
ERJU3R	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2			
ERJU6R	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4			

Test Item	Performance Requirements ⊿R	Test Conditions		
Resistance	Within Specified Tolerance	20 °C		
T. C. R.	Within Specified T. C. R.	+25 °C/+155 °C		
Overload	±2 %	Rated Voltage × 2.5, 5 s		
Resistance to Soldering Heat	±1 %	270 °C, 10 s		
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C(30 min.), 100 cycles		
High Temperature Exposure	±1 %	+155 °C, 1000 h		
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h		
Load Life in Humidity	±2 %	60 °C, 90 % to 95 %RH, Rated Voltage,		
Load Life III Humbally	12 70	1.5 h ON / 0.5 h OFF cycle , 1000 h		
Endurance at 70 °C	±2 %	70 °C, , Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		

Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type

Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type

102

Series: ERJ UP3, UP6, UP8

Features

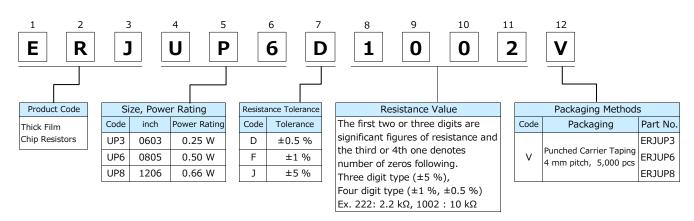
- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure
- ESD surge characteristics superior to standard metal film resistors
- High reliability… Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power ····· 0.25 W: 0603 inch / 1608 mm size (ERJUP3)

0.50 W: 0805 inch / 2012 mm size (ERJUP6)

0.66 W: 1206 inch / 3216 mm size (ERJUP8)

- Reference Standard · · · IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



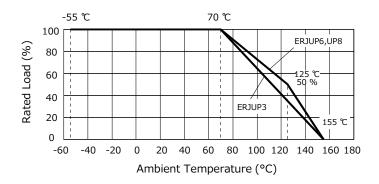
Ratings

	Part No. (inch size)	Power Rating ⁽¹⁾ at 70 °C (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resisi Rar (Ç	nge	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC-Q200 Grade		
NEV	ERJUP3	0.25	150	200	±0.5, ±1	10 to 1 M	(E24, E96)	±100	-55 to +155	Grade 0		
	(0603)	0.23	150	200	±5	1 to 1.5 M	(E24)	±200	-55 to +155	Grade 0		
	ERJUP6	NILIDC .		±0.5, ±1	10 to 1 M	(E24, E96)	±100					
	(0805)	0.50	400	600	±5	1 to 3.3 M	(E24)	R<10 Ω : –100 to +600	-55 to +155	Grade 0		
	(0003)					1 (0 3.3 14	(L24)	10 Ω≤R : ±200				
	ERJUP8						±0.5, ±1	10 to 1 M	(E24, E96)	±100		
	(1206)	0.66	0.66 500	1000	±5	1 to 10 M	(E24)	R<10 Ω : –100 to +600	-55 to +155	Grade 0		
	(1200)					1 (0 10 14)	(LZ7)	10 Ω≤R : ±200				

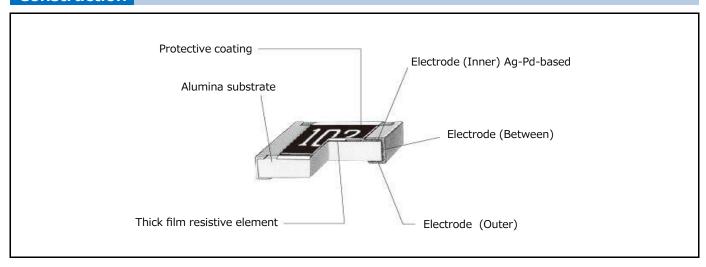
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Power Derating Curve

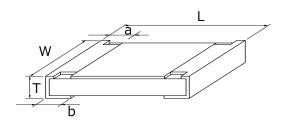
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



Construction

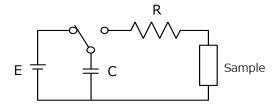


Dimensions in mm (not to scale)



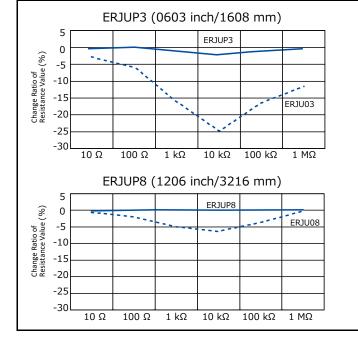
Dart No.	Dimensions (mm)								
Part No.	L	W	a	b	Т	(g/1000 pcs)			
ERJUP3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2			
ERJUP6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4			
ERJUP8	3.20+0.05/-0.20	1.6+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10			

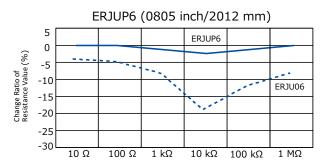
ESD Characteristic



R	R=0 Ω(\leq 1.5 kΩ) / 150 Ω($>$ 1.5 kΩ)
С	150 pF
Е	±3 kV

Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type (ERJUP Type) Anti-Sulfurated Thick Film Chip Resistors (ERJU Type)





%This data is for reference purposes.
Please check with the actual equipment before use.

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+155 °C
Overload	±2 %	ERJUP6 : Rated Voltag× 1.77, 5 s ERJUP3, ERJUP8 : Rated Voltag× 2.0 , 5 s
Resistance to Soldering Heat	D: ±0.5 %, F, J: ±1 %	270 °C, 10 s
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles
High Temperature Exposure	±1 %	+155 °C, 1000 h
Damp Heat, Steady State	±1 %	60 °C, 90 % ~ 95 %RH, 1000 h
Load Life in Humidity	±3 %	60 °C, 90 % ~ 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle , 1000 h
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h



Anti-Sulfurated High Power Chip Resistors / Wide Terminal Type

ROI

Series: ERJ C1

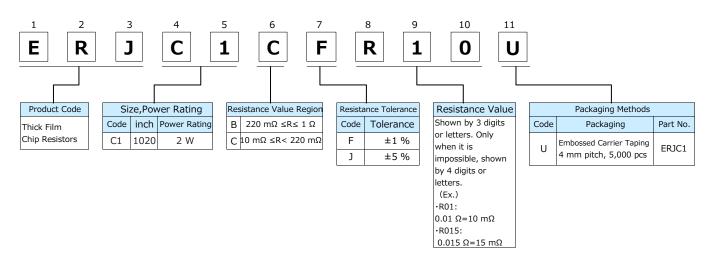
Features

- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure (Covered electrode)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended Applications

- Motor control circuit of the industrial equipment
- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems
- Current sensing for power supply circuits in a variety of equipment
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



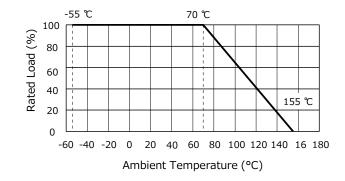
Ratings

Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /K)		Category Temperature Range (℃)	AEC- Q200 Grade
ERJC1 (1930)	2	±1	10 m to 1 (E24)	$10 \text{ m}\Omega \leq R < 22 \text{ m}\Omega$ $22 \text{ m}\Omega \leq R < 47 \text{ m}\Omega$ $47 \text{ m}\Omega \leq R < 100 \text{ m}\Omega$ $100 \text{ m}\Omega \leq R \leq 1 \Omega$: 0 to +200 : 0 to +150		Grade 0
(1020)		±5		$10 \text{ m}\Omega \leq R < 22 \text{ m}\Omega$ $22 \text{ m}\Omega \leq R < 100 \text{ m}\Omega$ $100 \text{ m}\Omega \leq R \leq 1 \Omega$			

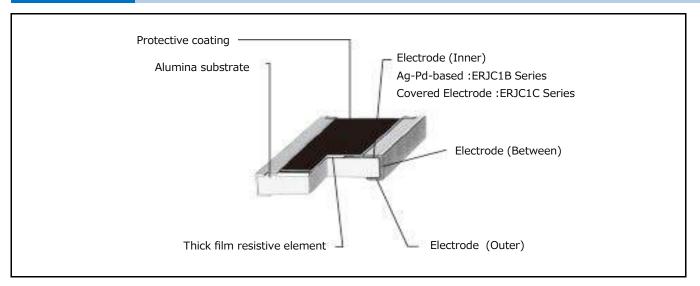
- (1) Use it on the condition that the case temperature is below the upper category temperature.
 - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\(Power Rating \times Resistance Value. \)
 - Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

Power Derating Curve

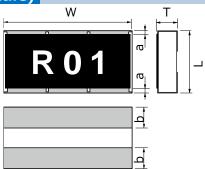
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



Construction

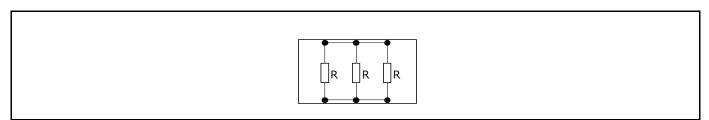


Dimensions in mm (not to scale)



Part No.			Dimensions (mm)	Mass (Weight)		
Part No.	L	W	Т	a	b	(g/1000 pcs)
ERJC1B	2 50+0 20	2.50±0.20 5.00±0.20 0.55±0.20		0.35±0.20	0.90±0.20	27
ERJC1C	2.30±0.20			0.60±0.20	0.90±0.20	27

Circuit Configuration





Test Item	Performance Requirements ⊿	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2 %	Rated Voltage× 2.0, 5 s
Resistance to Soldering Heat	±1 %	270 °C, 10 s
Rapid Change of Temperature	±2 %	-55 °C (30 min.) / +125 °C (30 min.), 1000 cycles
High Temperature Exposure	±1 %	+155 °C, 1000 h
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle , 1000 h
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h



Chip Resistors Array

Chip Resistors Array

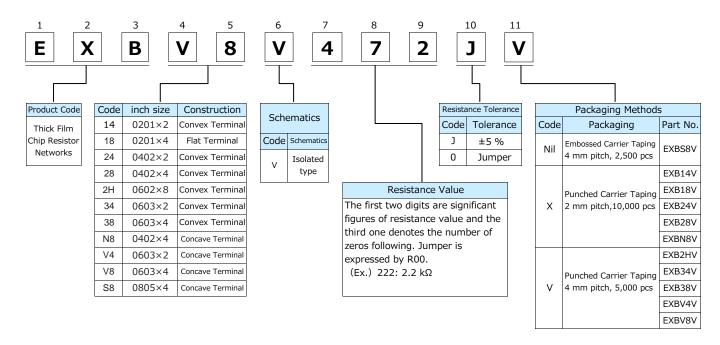
Series: EXB 14V, 18V, 24V, 28V, N8V, 2HV, 34V, V4V, 38V, V8V, S8V



Features

- High density
 - 2 resistors in 0.8 mm × 0.6 mm size / 0302 inch size: EXB14V
 - 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXB18V
 - 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXB24V
 - 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXB28V, N8V
 - 8 resistors in 3.8 mm \times 1.6 mm size / 1506 inch size : EXB2HV
 - 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXB34V, V4V
 - 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXB38V, V8V
 - 4 resistors in 5.1 mm × 2.2 mm size / 2009 inch size : EXBS8V
- Improvement of placement efficiency
 - Placement efficiency of Chip Resistor Array is two, four or eight times of the flat type chip resistor
- Reference Standard ··· IEC 60115-9, JIS C 5201-9, EIAJ RC-2129
- AEC-Q200 compliant (EXB2, EXB3)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



Ratings

[For Resistor]

Part No. (inch size)	Power Rating at 70 °C (W/element)	Limiting Element Voltage ⁽¹⁾ (V)	Maximum Overload Voltage ⁽²⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
EXB14V (0201×2)	0.031	12.5	25	±5	10 to 1 M (E24)		-55 to +125	-
EXB18V (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M (E24)		-55 to +125	-
EXB24V (0402×2)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXB28V (0402×4)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXB2HV (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M (E24)	R<10 Ω: -200 to +600	-55 to +125	Grade 1
EXB34V (0603×2)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXB38V (0603×4)	0.063	50	100	±5	1 to 1 M (E24)	10 Ω to 1 MΩ:	-55 to +125	Grade 1
EXBN8V (0402×4)	0.031	50	100	±5	10 to 1 M (E24)	±200	-55 to +125	-
EXBV4V (0603×2)	0.063	50	100	±5	10 to 1 M (E24)		-55 to +125	-
EXBV8V (0603×4)	0.063	50	100	±5	10 to 1 M (E24)		-55 to +125	-
EXBS8V (0805×4)	0.1	100	200	±5	10 to 1 M (E24)		-55 to +125	-

- (1) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (2) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

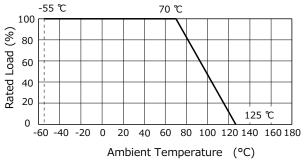
[For Jumper]

Part No.	Resistance(Ω)	Rated Current (A / element)	Maximum Overload Current (A) ⁽¹⁾
EXB14V		0.5	1
EXB18V		0.5	1
EXB24V		1	2
EXB28V		2	
EXB2HV		1	2
EXB34V	50 m Ω or less	1	2
EXB38V		1	2
EXBN8V		1	2
EXBV4V		1	2
EXBV8V		1	2
EXBS8V		2	4

(1) Overload test current

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.

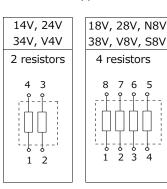


Construction(Example : Concave Terminal)

Protective coating Alumina substrate Electrode (Outer) resistive Electrode (Inner)

Schematics

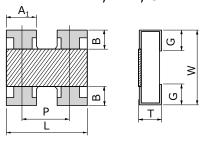
Isolated type

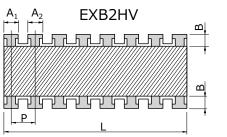


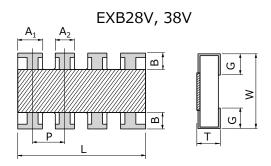
Dimensions in mm (not to scale)

(1) Convex Terminal type

EXB14V, 24V, 34V







Part No.		Dimensions (mm)							
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(g/1000 pcs)
EXB14V (0603X2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	_	0.15±0.10	(0.50)	0.15±0.10	0.5
EXB24V (1005×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	_	0.18±0.10	(0.65)	0.25±0.10	1.2
EXB28V (1005×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0
EXB2HV (1605×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0
EXB34V (1608×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15	_	0.30±0.20	(0.80)	0.30±0.20	3.5
EXB38V (1608×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0

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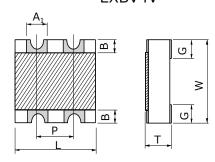
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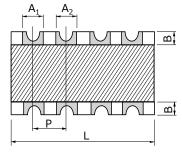
) Reference

(2) Concave Terminal type

EXBV4V



EXBN8V, V8V, S8V



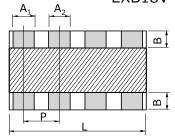
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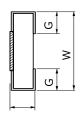
Part No.		Dimensions (mm)							Mass (Weight)
(inch size)	L	W	Т	A_1	A_2	В	Р	G	(g/1000 pcs)
EXBN8V (1005×4)	2.00±0.10	1.00±0.10	0.45±0.10	0.30±0.10	0.30±0.10	0.20±0.15	(0.50)	0.30±0.15	3.0
EXBV4V	1.60	1.60	0.60±0.10	±0.10 0.60±0.10	_	0.30±0.15	(0.80)	0.45±0.15	5.0
(1608×2)	+0.20/-0.10	+0.20/-0.10	0.00±0.10						
EXBV8V	3.20	1.60	0.60±0.10	0.60±0.10	0.60±0.10	0.30±0.15	(0.80)	0.45±0.15	10
(1608×4)	+0.20/-0.10	+0.20/-0.10	0.0010.10	0.0010.10	0.0010.10	0.30±0.13	(0.80)	0.43±0.13	10
EXBS8V	5.08	2.20	0.70±0.20	0.80±0.15	0.80±0.15	0.50±0.15	(1.27)	0.55±0.15	30
(2012×4)	+0.20/-0.10	+0.20/-0.10	0.70±0.20	0.00±0.13	0.00±0.13	0.30±0.13	(1.27)	0.55±0.15	30

() Reference

Dimensions in mm (not to scale)

(3) Flat Terminal type EXB18V





Part No.		Dimensions (mm)							Mass (Weight)
(inch size)	L	W	Т	A_1	A ₂	В	Р	G	(g/1000 pcs)
EXB18V (0603×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0

() Reference

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2 %	Rated Voltage× 2.5, 5 s Jumper type: Max. Overload Current, 5 s
Resistance to Soldering Heat	±1 %	270 °C, 10 s
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles
High Temperature Exposure	±1 %	+125 °C, 1000 h
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage (Jumper type: Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3 %	70 °C, Rated Voltage (Jumper type :Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h



Anti-Sulfurated Chip Resistors Array

Anti-Sulfurated Chip Resistors Array

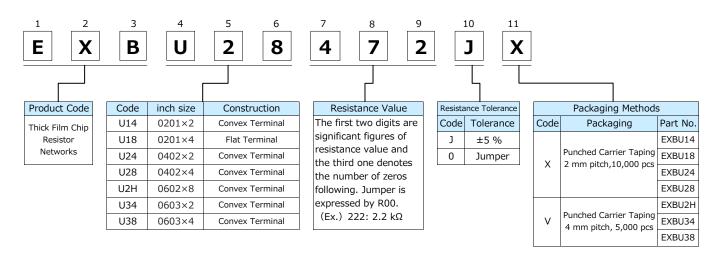


Series: EXB U14, U18, U24, U28, U2H, U34, U38

Features

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode
- High density
 - 2 resistors in 0.8 mm \times 0.6 mm size / 0302 inch size : EXBU14
 - 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size: EXBU18
 - 2 resistors in 1.0 mm \times 1.0 mm size / 0404 inch size : EXBU24
 - 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXBU28
 - 8 resistors in 3.8 mm \times 1.6 mm size / 1506 inch size : EXBU2H
 - 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXBU34
 - 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXBU38
- Improvement of placement efficiency
 - Placement efficiency of Chip Resistor Array is two, four or eight times of the flat type chip resistor
- Reference Standard ··· IEC 60115-9, JIS C 5201-9, EIAJ RC-2129
- AEC-Q200 compliant (EXBU2, EXBU3)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



Ratings

[For Resistor]

Part No. (inch size)	Power Rating at 70 °C (W/element)	Limiting Element Voltage ⁽¹⁾ (V)	Maximum Overload Voltage ⁽²⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
EXBU14 (0201×2)	0.031	12.5	25	±5	10 to 1 M (E24)		-55 to +125	-
EXBU18 (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M (E24)	R<10 Ω: -200 to +600	-55 to +125	-
EXBU24 (0402×2)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXBU28 (0402×4)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXBU2H (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M (E24)	10 Ω to 1 M Ω : ±200	-55 to +125	Grade 1
EXBU34 (0603×2)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXBU38 (0603×4)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1

- (1) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= $\sqrt{\text{Power Rating}} \times \text{Resistance Value}$, or Limiting Element Voltage listed above, whichever less.
- (2) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

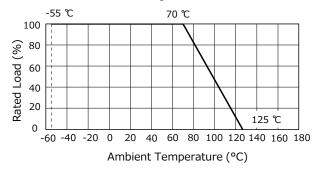
[For Jumper]

Part No.	Resistance(Ω)	Rated Current (A / element)	Maximum Overload Current (A) ⁽¹⁾
EXBU24			
EXBU28			
EXBU2H	100 m Ω or less	1	2
EXBU34			
EXBU38			

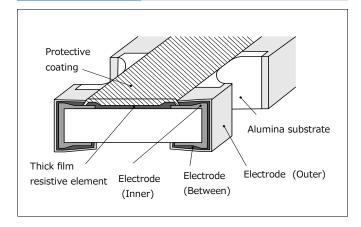
(1) Overload test current

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.

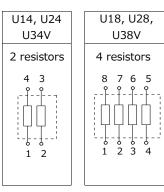


Construction



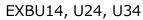
Schematics

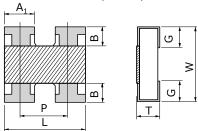
Isolated type

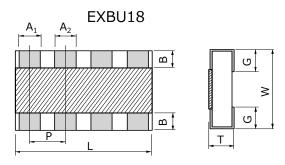


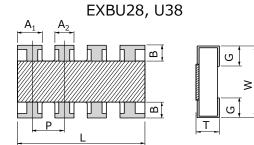
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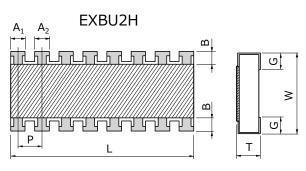
Dimensions in mm (not to scale)











Part No.				Dimensio	ns (mm)				Mass (Weight)
(inch size)	L	W	Т	A_1	A_2	В	Р	G	(g/1000 pcs)
EXBU14 (0201X2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	1	0.15±0.10	(0.50)	0.15±0.10	0.5
EXBU18 (0201×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0
EXBU24 (0402×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	_	0.18±0.10	(0.65)	0.25±0.10	1.2
EXBU28 (0402×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0
EXBU2H (0602×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0
EXBU34 (0603×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15		0.30±0.20	(0.80)	0.30±0.20	3.5
EXBU38 (0603×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0

Test Item	Performance Requirements ⊿R	Test Conditions				
Resistance	Within Specified Tolerance	20 °C				
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C				
Overload	±2 %	Rated Voltage× 2.5, 5 s Jumper type: Max. Overload Current, 5 s				
Resistance to Soldering Heat	±1 %	270 °C, 10 s				
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +125 °C (30 min.), 100 cycles				
High Temperature Exposure	±1 %	+125 °C, 1000 h				
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h				
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage (Jumper type: Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h				
Endurance at 70 °C	±3 %	70 °C, Rated Voltage (Jumper type :Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h				



Chip Resistors Networks

Chip Resistors Networks

102 102 = 121

Series: EXB D, E, A, Q

Features

- High density placing for digital signal circuits
 - ·Bussed 8 or 15 resistors for pull up/down circuits

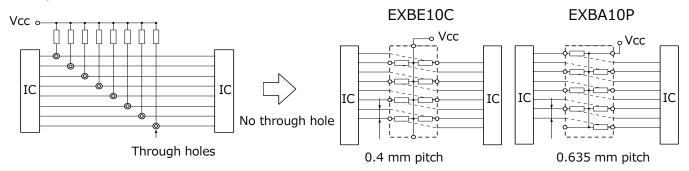
EXBD : $3.2 \text{ mm} \times 1.6 \text{ mm} \times 0.55 \text{ mm}$, 0.635 mm pitch EXBE : $4.0 \text{ mm} \times 2.1 \text{ mm} \times 0.55 \text{ mm}$, 0.8 mm pitch EXBA : $6.4 \text{ mm} \times 3.1 \text{ mm} \times 0.55 \text{ mm}$, 1.27 mm pitch EXBQ : $3.8 \text{ mm} \times 1.6 \text{ mm} \times 0.45 \text{ mm}$, 0.5 mm pitch

- •Available direct placing on the bus line by means of half pitch spacing without through-holes on PWB ("High density placing" is shown below)
- High speed mounting using conventional placing machine
- Reference Standard · · · IEC 60115-9, JIS C 5201-9, EIAJ RC-2130
- RoHS compliant

[High density placing]

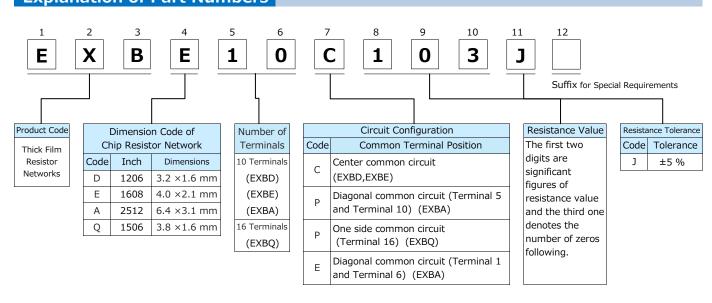
Pull up resistors

Direct placement on the bus line



■ As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

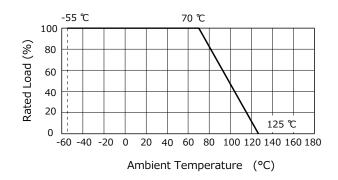


Rati	ings									
Part No. (inch size)	Resistance Range (Ω)	Resistance Tolerance (%)	Number of Terminals	Number of Resistors	Power Rating ⁽¹⁾ at 70 °C (W/element)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
EXBD (1206)					0.05 / element	25	50	±200	-55 to +125	-
EXBE (1608)	47 to 1 M (E12)	±5	10 terminals	8 element	0.063 / element	25	50	±200	-55 to +125	-
EXBA (2512)		13			0.063 / element	50	100	±200	-55 to +125	-
EXBQ (1506)	100 to 470 k (E6)		16 terminals	15 element	0.025 / element	25	50	±200	-55 to +125	-

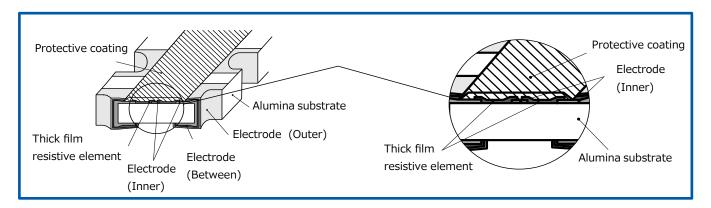
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (1) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= $\sqrt{\text{Power Rating}} \times \text{Resistance Value}$, or Limiting Element Voltage listed above, whichever less.
- (2) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Power Derating Curve

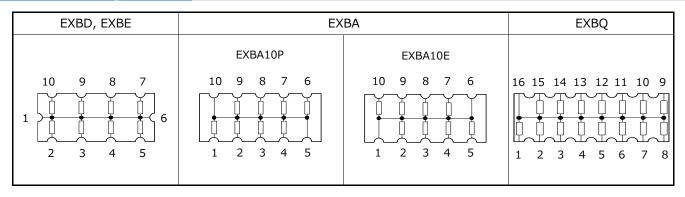
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



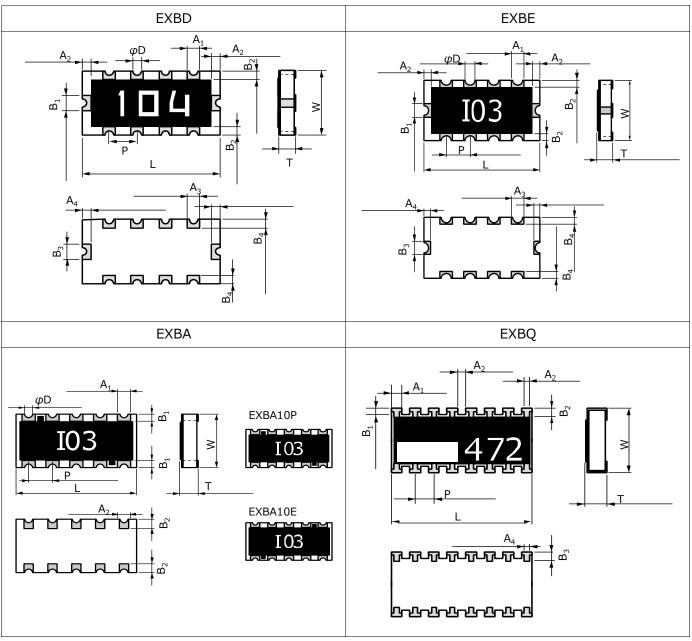
Construction(Example : EXBD)



Circuit Configuration



Dimensions in mm (not to scale)



			Di	mensions (mi	m)			Mass (Weight)		
Part No.	L	W		A ₁	A ₂	B ₁	B ₂	(g/1000 pcs)		
	3.20±0.15	1.60±0.15	0.55±0.10	0.33±0.15	0.2±0.1	0.40±0.15	0.2±0.1	, , ,		
EXBD	A_3	A_4	B ₃	B ₄	Р	φD		10		
	0.3±0.1	0.25±0.10	0.40±0.15	0.35±0.15	0.635±0.10	0.2±0.1				
	Dimensions (mm)									
Part No.	L	W	Т Т	A ₁	A ₂	B ₁	B ₂	Mass (Weight) (g/1000 pcs)		
	4.0±0.2	2.1±0.2	0.55±0.10	0.5±0.2	0.3±0.2	0.5±0.2	0.25±0.20	, , ,		
EXBE	A ₃	A_4	B ₃	B ₄	Р	φD		16		
	0.4±0.2	0.35±0.20	0.5±0.2	0.4±0.2	0.8±0.1	0.3+0.1/-0.2				
			Di	mensions (mi	m)			Mass (Weight)		
Part No.	L W T A ₁ B ₁ A ₂ B ₂							(g/1000 pcs)		
	6.4±0.2	3.1±0.2	0.55±0.10	0.7±0.2	0.3±0.2	0.5±0.2	0.5±0.20			
EXBA	Р	φD						40		
	1.27±0.10	0.3+0.1/-0.2								
	Dimensions (mm)									
Part No.	L	W		A ₁	A ₂	A_3	B ₁	Mass (Weight) (g/1000 pcs)		
	3.8±0.2	1.6±0.2	0.45±0.10	0.3±0.1	0.2±0.1	0.15+0.15/-0.05	0.15+0.15/-0.05			
EXBQ	B ₂	A_4	B ₃	Р				9		
_	0.25±0.15	0.15+0.20/-0.05	0.30±0.15	0.5±0.1				1		



Chip Resistors Networks

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±3 %	Rated Voltage× 2.5, 5 s
Resistance to Soldering Heat	±1 %	260 °C ±5 °C, 5 s ±1 s
Rapid Change of Temperature	±2 %	-55 °C (30 min.) / +125 °C (30 min.), 5 cycles
High Temperature Exposure	±3 %	+125 °C, 100 h
Load Life in Humidity	±3 %	60 °C±2 °C, 90 % to 95 %RH, Rated Power × 0.1, 1.5 h ON / 0.5 h OFF cycle, 500 h
Endurance at 70 °C	±5 %	70 °C±2 ℃, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h



Chip Attenuator

ea (64)

Series: EXB 14AT, 24AT

Features

- Unbalanced π type attenuator circuit in one chip EXB14AT(0.8 mm×0.6 mm), EXB24AT(1.0 mm×1.0 mm)
- Reduced mounting area :

EXB14AT : About 60 % smaller than the area of an attenuator circuit consisting of three 0603 chip resistors, almost equal to the area of three 0402 chip resistors

EXB24AT : About 50 % smaller than the area of an attenuator circuit consisting of three 1005 chip resistors, almost equal to the area of three 0603 chip resistors

• Mounting cost reduction: (Only 1 chip placed as compared to 3)

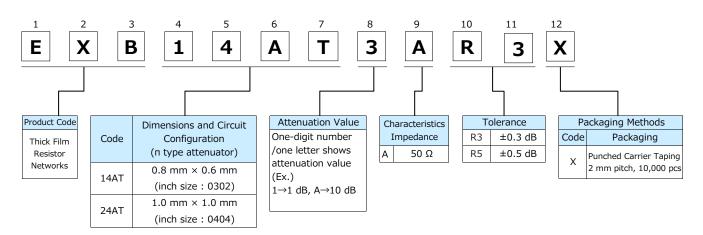
Attenuation: 1 dB to 10 dB

RoHS compliant

Recommended Applications

- Attenuation / level control / impedance matching of high frequency (communication signalling equipment cellular phones(GSM, CDMA, PDC, etc.), PHS, PDAs)
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

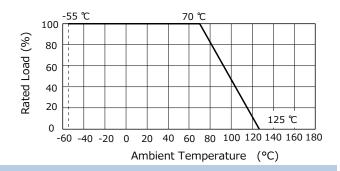


Ratings	
Part No.	EXB14AT, EXB24AT
Attenuation Value	1 dB, 2 dB, 3 dB, 4 dB, 5 dB, 6 dB, 10 dB*
Attenuation Value Tolerance	1 dB, 2 dB, 3 dB, 4 dB, 5dB: ±0.3 dB
Attenuation value Tolerance	6 dB, 10 dB : ±0.5 dB
Characteristic Impedance	50 Ω
Power Rating at 70 °C	0.04 W/ package
Frequency Range	DC to 3.0 GHz
VSWR (Voltage Standing Wave Ratio)	1.3 max.
Number of Resistors	3 resistors
Number of Terminals	4 terminals
Category Temperature Range	−55 °C to +125 °C

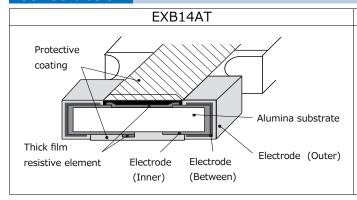
^{*} Please inquire about the other Attenuator value

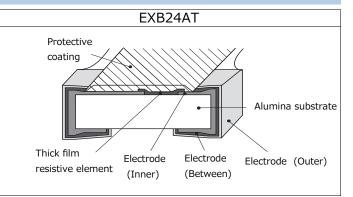
Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

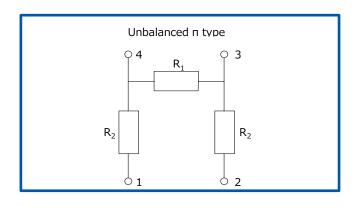


Construction

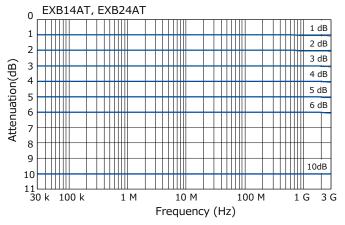




Circuit Confi guration

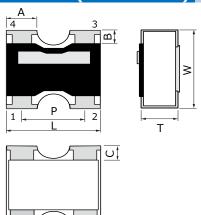


Attenuation-Frequency Characteristics

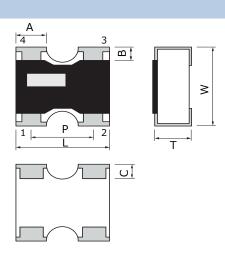


Dimensions in mm (not to scale)

EXB14AT



EXB24AT



< Marking Configuration> The bar marking for recognizing terminal direction is located on the side of terminal 3, 4.

< Marking Configuration> The bar marking for recognizing terminal direction is located on the side of terminal 4.

Part No.				Dimensions (mm	1)			Mass (Weight)
1 41 2 1101	L	W	T	Α	В	С	P(typical value)	(g/1000 pcs)
EXB14AT	0.80 ± 0.10	0.60±0.10	0.35 ± 0.10	0.35 ± 0.10	0.15 ± 0.10	0.15±0.10	0.50	0.7
EXB24AT	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	0.15±0.10	0.25±0.10	0.65	1.1

Products	Surface	Mount Resistors Seri	es	Packaging (Standard Quantity : pcs/reel)						
Products			Sizo mm	Pressed	Punched	Punched	Embossed			
ERJXGN 0402(01005) 220,000 *	Products	Part No.								
ERJIGN					(2 mm pitch)	(4 mm pitch)				
FRJ2CE			· · · · · · · · · · · · · · · · · · ·		_		40,000 **			
Thick Film Chip Resistors Fire Resistors Chip Resistors ERJ36E 2012(0805) — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — — 5,000 — — 5,000 — — — 5,000 — — — 5,000 — — — — 5,000 — — — — 5,000 — — — — 5,000 — — — — 5,000 — — — — 6,000 — — — — 6,000 — — — — 6,000 — — — — 6,000 — — — — 6,000 — — — — 6,000 — — — — 6,000 — — — — 6,000 — — — — 6,000 — — — 6,000 — — — 6,000 — — — 6,000 — — — 6,000 — — — 6,000 — — — 6,000 — — 6,000 — — 6,000 — — — 6,000 — — 6,000 — — 6,000 — — 6,000 — — 6,000 — — 6,000 — — 6,000 — — 6,000 — — 6,000 — — 6,000 — — 6,000 — — 6,000 — — 6,000 — — 6,000 — — 6,000 — — 6,000 — — 6,000 — — 6,000 — — 6,000 — 6,000 — — 6,000 —			· · ·	15,000	_	_	_			
Thick Film Chip Resistors (ER/BGE 2012(0805) — — — 5,000 — — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — 5,000 — — — 5,000 — — — 5,000 — — — 5,000 — — — — 5,000 — — — — 5,000 — — — — 5,000 — — — — 5,000 — — — — 4,000 — — — — 4,000 — — — — — 4,000 — — — — — — — — — — — — — — — — — —				_	10,000, 20,000	_	_			
Chip Resistors			, ,	_	_	5,000	_			
ERJ14 3225(1210) 5,000 ERJ12 4532(1812) 5,000 ERJ12 5025(2010) 5,000 ERJ1T 6432(2512) 4,000 ** 40,000 ** ERJ1T 6432(2512) 4,000 ** 40,000 ** ERJ1GN/1RH 6630(2011) 15,000 40,000 ** ERJ1GN/1RH 6630(2011) 15,000 40,000 ** ERJ1GN/1RH 6630(2011) 15,000	Thick Film	ERJ6GE		_	_	5,000	_			
ERJ12	Chip Resistors			_	_	5,000	_			
ERJ12Z 5025(2010) — — — — 5,000 ERJ1T 6432(2512) — — — 4,000 ** ERJXGN 0402(01005) 20,000 * — — 40,000 ** ERJXGN 0402(01005) 15,000 — — — 40,000 ** ERJXGN 15,000 — — — — 40,000 ** ERJXGN 0402(01005) 15,000 — — — — — — — — — — — — — — — — — —		ERJ14	3225(1210)	_	_	_	5,000			
ERJIT		ERJ12	4532(1812)	_	_	_	5,000			
REJISGN		ERJ12Z	5025(2010)	_	_	_	5,000			
Precision Filan		ERJ1T	6432(2512)	_	_	_	4,000			
Precision Thick Film ERJ3RB/3RE/3EK 1005(0402) 5,000 5,000		ERJXGN	0402(01005)	20,000 *	_	_	40,000 **			
Precision Thick Film ERJ3RB/3RE/3EK 1005(0402) 10,000 5,000 ERJ3RB/3RE/3EK 1008(0603) 5,000 5,00		ERJ1GN/1RH	0603(0201)	15,000	_	_	_			
Precision Thick Film ERJ3RB/3RE/3EK 1608(0603)		ERJ2RC/2RH/2RK	1005(0402)	_	10,000	_	_			
Precision Filt			1608(0603)	_	_	5,000	_			
FRJBEN 3216(1206)			2012(0805)	_	_	· · · · · · · · · · · · · · · · · · ·	_			
ERJ14N 3225(1210) 5,000 ERJ12N 4532(1812) 5,000 ERJ12N 4532(1812) 5,000 ERJ1TN 6432(2512) 4,000 ERJ1TN 6432(2512) 4,000 ERJ1TN 6432(2512) 4,000 ERJ1TN 6432(2512) 4,000 4,000 ERJ1TN 6432(2512) 4,000			3216(1206)	_	_	· · · · · · · · · · · · · · · · · · ·	_			
ERJ12N	Chip Resistors			_	_	_	5,000			
ERJ12S 5025(2010)				_	_	_				
REJITN			`	_	_	_				
Metal Film (Thin Film) (Thin Film) ERA1A 0603(0201) 15,000 —			, ,	_	_					
(Thin Film) ERA2A/2V 1005(0402) — 10,000 — — Chip Resistors, High Reliability Type ERA3A/3V/3K 1608(0603) — — 5,000 — Type ERA6A/6V/6K 2012(0805) — — 5,000 — ERJ2LW/2BW 1005(0402) 10,000 — — — ERJ2BS/2BQ 1005(0402) — 10,000 — — ERJ3L/3B/3R/L03 1608(0603) — — 5,000 — ERJ6L/6B/6C ERJ6L/6B/6C 2012(0805) — — 5,000 — ERJ6L/6B/6C ERJ8B/8C/8R/L08 3216(1206) — — 5,000 — Resistors/Low ERJ8B/8C/8R/L08 3216(1206) — — 5,000 — Resistors/Low ERJ14R/14 3225(1210) — — — 5,000 ERJ12/L12 4532(1812) — — — 5,000 ERJ1TR 6432(2512) — — </td <td>Metal Film</td> <td></td> <td></td> <td>15.000</td> <td>_</td> <td>_</td> <td></td>	Metal Film			15.000	_	_				
Chip Resistors, High Reliability Type					10 000	_	_			
High Reliability Type ERA6A/6V/6K 2012(0805) -	•	-	, ,	_	_	5 000	_			
Type	•		, ,		_		_			
ERJ2LW/2BW 1005(0402) 10,000 -	-		, ,		_	•				
ERJ2BS/2BQ 1005(0402) — 10,000 — — — ERJ3L/3B/3R/L03 1608(0603) — — 5,000 — ERJ6L/6B/6C ERJ6D/6R/L06 2012(0805) — — 5,000 — Resistance Type ERJ14B/14R/L14 3225(1210) — — 5,000 — 5,000 ERJ1TR 6432(2512) — — — 5,000 ERJ1TR 6432(2512) — — — 4,000 ERJ1TR 6432(2512) — — — 3,000 ERJ1TR 6432(2512) — — — — — — 3,000 ERJ1TR 6432(2512) — — — — — — — 3,000 ERJ1TR 6432(2512) — — — — — — — — — — 3,000 ERJ1TR 6432(2512) — — — — — — — — — — — — — — — — — — —				10.000	_					
ERJ3L/3B/3R/L03 1608(0603) -			, ,	10,000	10.000					
ERJ6L/6B/6C ERJ6D/6R/L06 2012(0805) -					10,000	F 000				
Thick Film Chip Resistors/Low Resistance Type ERJ8B/8C/8R/L08 ERJ14B/14R/L14 ERJ12R/L12 ERJ12R/L12 ERJ12Z/L1D ERJ1TR ERJ1LW ERJ1LW Current Sensing Resistors, Metal Plate Type ERJA1 ERJA1 ERJB1/ERJC1(1) ERJB2/ERJD2(2) ERJB2/ERJD2(2) ERJB2/ERJD2(2) ERJB2/ERJD2(2) ERJB2/ERJD2(2) ERJ16(1206) — — — — — — — — — — — — — — — — — —			1000(0003)		_	3,000				
Resistance Type ERJ14B/14R/L14 3225(1210) - - - 5,000 5,000 ERJ12R/L12 4532(1812) - - - - 5,000 ERJ12Z/L1D 5025(2010) - - - - 5,000 ERJ1TR 6432(2512) - - - - 4,000 ERJL1W 6432(2512) - - - - 3,000 ERJL1W 6432(2512) - - - - 2,000 ERJMS4 6432(2512) - - - - 2,000 ERJMB1 2550(1020) - - - - 3,000 ERJMB1 3264(1225) - - - - 4,000 ERJB1/ERJC1 ⁽¹⁾ ERJD1 ⁽²⁾ 2550(1020) - - - - 5,000 - - - 5,000 - ERJB2/ERJD2 ⁽²⁾ 1632(0612) - - - 5,000 - - - - - - - - -	Thick Film		2012(0805)	_	_	5,000	_			
Resistance Type ERJ14B/14R/L14 3225(1210) 5,000 ERJ12R/L12 4532(1812) 5,000 ERJ12Z/L1D 5025(2010) 5,000 ERJ1TR 6432(2512) 4,000 ERJL1W 6432(2512) 3,000 Current Sensing Resistors, Metal Plate Type ERJMS4 6432(2512) 2,000 ERJMB1 2550(1020) 3,000 ERJMB1 3264(1225) 4,000 ERJB1/ERJC1(1) ERJB1/ERJC1(1) ERJB1/ERJC1(1) ERJB1/ERJC1(2) ERJD1(2) ERJB1/ERJC1(2) 5,000 ERJB2/ERJD2(2) 1632(0612) 5,000 ERJB2/ERJD2(2) 1632(0612) 5,000 ERJB2/ERJD2(2) 1632(0612) 5,000 ERJB2/ERJD2(2) 1632(0612) 5,000 ERJB1/ERJC1(2) 1632(0612) 5,000 ERJB1/ERJC1(2) 1632(0612) ERJB1/ERJC1(2) 1632(0612) ERJB1/ERJC1(2) 1632(0612) ERJB1/ERJC1(2) 1632(0612) ERJB1/ERJC1(2) 1632(0612) ERJB1/ERJC1(2) 1632(0612) ERJB1/ERJC1(2) 1632(0612) ERJB1/ERJC1(2) 1632(0612) ERJB1/ERJC1(2) 1632(0612) ERJB1/ERJC1(2) 1632(0612) ERJB1/ERJC1(2) 1632(0612) ERJB1/ERJC1(2) 1632(0612) ERJB1/ERJC1(2) 1632(0612) ERJB1/ERJC1(2) 1632(0612) ERJB1/ERJC1(2) 1632(0612) ERJB1/ERJC1(2) 1632(0612) -	Chip Resistors/Low	ERJ8B/8C/8R/L08	3216(1206)	_	_	5,000	_			
ERJ12R/L12	Resistance Type	ERJ14B/14R/L14	3225(1210)	_	_	_	5,000			
ERJ12Z/L1D 5025(2010) — — — 5,000 ERJ1TR 6432(2512) — — — 4,000 ERJ1W 6432(2512) — — — 3,000 Current Sensing Resistors, Metal Plate Type ERJMS4 6432(2512) — — — 2,000 High Power Chip Resistors/Wide Terminal Type ERJB2/ERJD2 ⁽²⁾ 1632(0612) — — 5,000 —				_	_	_				
ERJ1TR 6432(2512) — — — 4,000 ERJL1W 6432(2512) — — — 3,000 Current Sensing Resistors, Metal Plate Type ERJMS4 6432(2512) — — — 2,000 High Power Chip Resistors/Wide Terminal Type ERJB2/ERJD2 ⁽²⁾ 1632(0612) — — 5,000 —			, ,	_	_	_				
ERJL1W 6432(2512) — — — 3,000 Current Sensing Resistors, Metal Plate Type ERJMS4 6432(2512) — — — — 2,000 High Power Chip Resistors/Wide Terminal Type ERJB2/ERJD2 ⁽²⁾ 1632(0612) — — 5,000 —				_	_	_				
Current Sensing Resistors, Metal Plate Type ERJMS4 6432(2512) — — — 2,000 High Power Chip Resistors/Wide Terminal Type ERJB1/ERJC1 ⁽¹⁾ ERJB2/ERJD2 ⁽²⁾ 2550(1020) — — — — 4,000 ERJB2/ERJD2 ⁽²⁾ 1632(0612) — — — 5,000 —				_	_	_				
Plate Type ERJMB1 2550(1020) — — — 3,000 High Power Chip Resistors/Wide Terminal Type ERJB1/ERJC1 ⁽¹⁾ ERJD1 ⁽²⁾ 2550(1020) — — — — 5,000 —	_			_	_	_				
High Power Chip Resistors/Wide Terminal Type ERJB2/ERJD2 ⁽²⁾ 2550(1020) — — — 5,000 — 5,000 —	· ·	ERJMB1	2550(1020)	_	_	_	3,000			
High Power Chip Resistors/Wide Terminal Type ERJB2/ERJD2 ⁽²⁾ 2550(1020) — — — 5,000 — 5,000 —		ERJA1	3264(1225)	_	_	_	4,000			
Terminal Type ERJB2/ERJD2 ⁽²⁾ 1632(0612)	9	ERJB1/ERJC1 ⁽¹⁾		_	_	_				
	Terminal Type		1632(0612)	_	_	5.000	_			
		ERJB3	1220(0508)	_	_	5,000	_			

^{*}W8P2 : Width 8 mm, Pitch 2 mm, ** W4P1 : Width 4 mm, Pitch 1 mm

⁽¹⁾ Anti-Sulfurated High Power Chip Resistors / Wide Terminal Type

⁽²⁾ Low TCR High Power Chip Resistors / Wide Terminal Type



Surface	Mount Resistors Se	ries	Packaging (Standard Quantity : pcs/reel)							
		Size mm	Pressed	Punched	Punched	Embossed				
Products	Part No.	(inch)	Carrier Taping	Carrier Taping	Carrier Taping	Carrier Taping				
		` '	(2 mm pitch)	(2 mm pitch)	(4 mm pitch)	(4 mm pitch)				
High Precision Thick	ERJPB3	1608(0603)	_	_	5,000	_				
Film Chip Resistors	ERJPB6	2012(0805)	_	_	5,000	_				
	ERJPA2	1005(0402)	_	10,000	_	_				
Anti-Surge Thick	ERJP03/PA3	1608(0603)	_	_	5,000	_				
Film Chip Resistors	ERJP06	2012(0805)	_	_	5,000	_				
Tilli Cilip Resistors	ERJP08	3216(1206)	_	_	5,000	_				
	ERJP14	3225(1210)	_	_	_	5,000				
Austi Dulas Thisle	ERJT06	2012(0805)	_	_	5,000	_				
Anti-Pulse Thick	ERJT08	3216(1206)	_	_	5,000	_				
Film Chip Resistors	ERJT14	3225(1210)	_	_	_	5,000				
	ERJU0X	0402(01005)	20,000	_	_	_				
	ERJU01	0603(0201)	15,000	_	_	_				
	ERJS02/U02	1005(0402)	_	10,000	_	_				
	ERJS03/U03	1608(0603)	_	-	5,000	_				
Anti-Sulfurated	ERJS06/U06				•	_				
Thick Film	ERJU6S/U6Q	2012(0805)	_	_	5,000					
Chip Resistors		2216/1206\			F 000					
Chip Resistors	ERJS08/U08	3216(1206)	_	_	5,000					
	ERJS14/U14	3225(1210)	_	_	_	5,000				
	ERJS12/U12	4532(1812)	_	_	_	5,000				
	ERJS1D/U1D	5025(2010)	_	_	_	5,000				
	ERJS1T/U1T	6432(2512)	_	_	_	4,000				
Anti-Sulfurated	ERJU2R	1005(0402)	_	10,000	_	_				
Thick Film Chip Resistors / Precision	ERJU3R	1608(0603)	_	_	5,000	_				
Type	ERJU6R	2012(0805)	_	_	5,000	_				
	ERJUP3	1608(0603)	_	_	5,000	_				
Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge	ERJUP6	2012(0805)	_	_	5,000	_				
Type	ERJUP8	3216(1206)	_	_	5,000	_				
	EXB14V	0806(0302)	_	10,000	_	_				
	EXB24V	1010(0404)	_	10,000	_	_				
	EXB34V	1616(0606)	_	_	5,000	_				
	EXBV4V	1616(0606)	_	_	5,000	_				
	EXB18V	1406(0502)	_	10,000	_	_				
Chip Resistor	EXB28V	2010(0804)	_	10,000	_	_				
Array	EXBN8V	2010(0804)	_	10,000	_	_				
	EXB38V	3216(1206)	_	-	5,000	_				
	EXBV8V	3216(1206)	_	_	5,000	_				
	EXBS8V	5022(2009)		_	_	2,500				
	EXB2HV	3816(1506)			5,000	2,300				
			_	10.000	3,000	_				
	EXBU14	0806(0302)	_	10,000	_	_				
	EXBU18	1406(0502)	_	10,000	_	_				
Anti-Sulfurated	EXBU24	1010(0404)	_	10,000	_ 	_				
Chip Resistor Array	EXBU34	1616(0606)	_	_	5,000	_				
·	EXBU28	2010(0804)	_	10,000		_				
	EXBU38	3216(1206)	_	_	5,000	_				
	EXBU2H	3816(1506)	_	_	5,000	_				
	EXBD	3216(1206)	_	_	5,000	_				
Chip Resistor	EXBE	4021(1608)	_	_	_	4,000				
Networks	EXBA	6431(2512)	_	_	_	4,000				
	EXBQ	3816(1506)	_	_	5,000	_				
	EXB14AT	0806(0302)	_	10,000	_	_				
Chip Attenuator	EXB24AT	1010(0404)	_	10,000	_	_				



Pressed Punched Embosse P₁ P₂ P₀ P₁ P₂ P₀ P₁ P₂ P₀ P₁ P₁ (2 mm pitch) φ D₁ (Only Emboss)

Pressec	l Carrier	Tapıng	j (2 mi	m Pitci	1)								
● Chip Resis	● Chip Resistors / Precision Chip / Metal Film(Thin Film)Chip / Low Resistance / Anti-Sulfurated (Unit:mm)												
Part No.	Size mm (inch)	Α	В	W	F	Е	P ₁	P_2	P ₀	φD_0	Т		
ERJXGN	0402	0.24±0.03	0.45+0.03								0.31±0.05		
ERJU0X	0402	0.24±0.03	0.43±0.03										
ERJ1GN													
ERJ1R□	0603	0.30+0.05	0.60+0.05			. ==				1.50	0.42±0.05		
ERJU01	0603	0.38±0.05	0.06±0.05	8.00±0.20	3.50±0.05	1./5±0.10	2.00±0.10	2.00±0.05	4.00±0.10	+0.10/0	0.42±0.05		
ERA1A													
ERJ2LW	1005	0.68±0.10	1.20±0.10	1							0.60±0.05		
ERJ2BW	1005	0.67±0.10	1.17±0.10	1							0.61±0.05		

Punche	d Carrie	Tapin	g (2 m	m Pitc	h)							
 Chip Resist 	• Chip Resistors / Precision Chip / Metal Film(Thin Film)Chip / Low Resistance / Anti-Surge / Anti-Sulfur / Metal Foil Type (Unit:mm)											
Part No.	Size mm (inch)	Α	В	W	F	E	P ₁	P_2	P_0	φD_0	Т	
ERJ2 ERJPA2 ERJ 2 ERJ 2 ERA2 ERA2	1005	0.67±0.05	1.17±0.05	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.52±0.05	

• Chip Resi	● Chip Resistor Array / Anti-Sulfurated Chip Resistor Array / Chip Attenuator (Unit:mm)											
Part No.	Size mm (inch)	Α	В	W	F	Е	P ₁	P_2	P_0	φD_0	Т	
EXB14V	0806	0.70	0.95									
EXB14AT	0800	+0.10/-0.05	+0.05/-0.10									
EXB18V	1406		1.60±0.10									
EXB24V										1 50		
EXBU24	1010		1.20±0.10	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50	0.52±0.05	
EXB24AT		1.20±0.10								+0.10/0		
EXB28V												
EXBU28	2010		2.20±0.10									
EXBN8V												

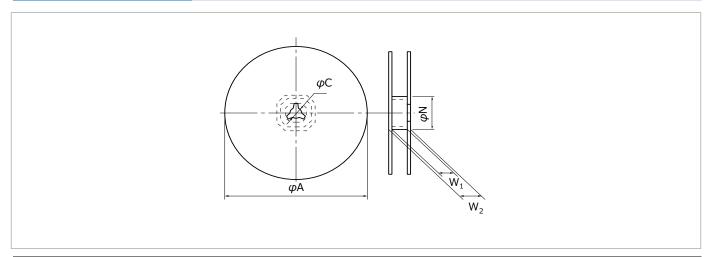
Punched Carrier Taping (4 mm Pitch) • Chip Resistors / Precision Chip / Metal Film(Thin Film)Chip / Low Resistance / High Power / High Precision / Anti-Surge /

Anti-Pulse	e / Anti-Sulfur	ated								(Unit	: mm)
Part No.	Size mm (inch)	Α	В	W	F	Е	P ₁	P_2	P_0	φD_0	Т
ERJ3 □ ERJ3LW(10mΩ) ERJ3BW ERJ□□3 ERJ□3□	1608	1.10±0.10	1.90±0.10								0.70±0.05
ERJ3LW(5mΩ)											
ERJ6□ ERJ□□6 ERJ□6□ ERA6□	2012	1.65±0.15		8.00±0.20	3.50±0.05	1.75±0.10	4.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.84±0.05
ERJB3	1220										
ERJ6BW ERJ6LW ERJ6C	2012	1.55±0.15	2.30±0.20								0.94±0.05
ERJ8 U ERJ8 U ERJ U B ERA8 U	3216	2.00±0.15	3.60±0.20								0.84±0.05
ERJB2 ERJD2	1632										

EXB34V 1616 1.95±0.20 3.60±0.20		stor Array / A	1			, , ,							t : mm)						
195±0.20 3.60±0.20 3.60±0.20 3.60±0.20 3.60±0.20 3.50±0.05 1.75±0.10 4.00±0.10 2.00±0.05 4.00±0.10 1.50 4.00±0.10	Part No.	Size mm (inch)	Α	В	W	F	Е		P ₁	P_2	P ₀	φD_0	Т						
SABLIS SALE	EXBU34	1616		1.95±0.20															
A	EXBU38	3216	1.0510.15	3.60±0.20									0.70±0.0						
1.0		3816	1.95±0.15	4.10±0.15	8.00±0.20	3.50±0.05	1.75±0.	10 4.00	±0.10	2.00±0.05	4.00±0.10								
EXBORD 3216 2.00±0.20 3.60±0.20	EXBV4V	1616		1.95±0.20								+0.10/0	0.84±0.0						
Embossed Carrier Taping (1 mm Pitch) Chip Resistors Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 OSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 T QSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 T QSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 T QSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 T QSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 T QSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 T QSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 T QSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 T QSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 T QSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 T QSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 T QSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 T QSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 T QSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 QD0 T T QSENUTE (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P	EXBV8V	3216		3.60±0.20									0.04±0.0						
Embossed Carrier Taping (1 mm Pitch) ◆ Chip Resistors (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 ΦD₀ D0 ERIXGN 0402 0.25±0.05 0.45±0.05 4.00±0.20 1.80±0.05 0.90±0.10 1.00±0.10 1.00±0.10 2.00±0.10 0.80±0.10 0.5 Embossed Carrier Taping (4 mm Pitch) ◆ Chip Resistors / Precision Chip / Low Resistance / High Power / Anti-Surge / Anti-Pulse / Anti-Sulfurated (Unit: m Part No. Size mm (inch) A B W F E P1 P2 P0 ΦD₀ T 4.00 PRI14 3225 2.80±0.20 3.50±0.20 8.00±0.30 3.50±0.05 1.75 4.00 2.00 4.00 1.00±0.10 PRI12 3225 2.80±0.20 5.30±0.20 12.00 5.50±0.20 ±0.10 ±0.10 ±0.10 ±0.10 ±0.10 ±0.10 ±0.10 ±0.10 ±0.10 ±0.10 ±0.10 ±0.10 ±0.10 ±	EXBD	3216	2.00±0.20	3.60±0.20									0.84±0.1						
Ochip Resistors Cunit : m Part No. Size mm (inch) A B W F E P₁ P₂ P₀ Φ D₀ P₀ ERJXGN 0402 0.25±0.05 0.45±0.05 4.00±0.20 1.80±0.05 0.90±0.10 1.00±0.10 1.00±0.10 2.00±0.10 0.80±0.10 0.58 Embossed Carrier Taping (4 mm Pitch) • Chip Resistors / Precision Chip / Low Resistance / High Power / Anti-Surge / Anti-Pulse / Anti-Sulfurated (Unit : m Part No. Size mm (inch) A B W F E P₁ P₂ P₀ Φ D₀ T 4.00 ERD114 3225 2.80±0.20 3.50±0.20 8.00±0.30 3.50±0.05 1.75 4.00 2.00 4.00 1.50 1.00±0.10 +0.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 1.00±0.10 <td>EXBQ</td> <td>3816</td> <td>1.90±0.20</td> <td>4.10±0.20</td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td>0.64±0.0</td>	EXBQ	3816	1.90±0.20	4.10±0.20									0.64±0.0						
Part No. Size mm (inch) A B W F E P₁ P₂ P₀ φ D₀ ERIXGN 0402 0.25±0.05 0.45±0.05 4.00±0.20 1.80±0.05 0.90±0.10 1.00±0.10 1.00±0.10 2.00±0.10 0.80±0.10 0.5 ERIDGN Chip Resistors / Precision Chip / Low Resistance / High Power / Anti-Surge / Anti-Pulse / Anti-Sulfurated (Unit : m Part No. Size mm (inch) A B W F E P₁ P₂ P₀ Φ D₀ T 4 RENITIC 4532 3.50±0.20 3.50±0.20 4.80±0.20 1.75 4.00 2.00 4.00 1.50 +0.10/0	Emboss	ed Carri	er Tapi	ing (1	mm Pi	tch)													
ERJISGN 0402 0.25±0.05 0.45±0.05 4.00±0.20 1.80±0.05 0.90±0.10 1.00±0.10 1.00±0.10 1.00±0.10 0.80±0.10 0.	● Chip Resi	stors											t : mm)						
Embossed Carrier Taping (4 mm Pitch) ◆ Chip Resistors / Precision Chip / Low Resistance / High Power / Anti-Surge / Anti-Pulse / Anti-Sulfurated (Unit : m Part No. Size mm (inch) A B W F E P P1 P2 P0 ΦD0 T G0. (Unit : m Part No. Size mm (inch) A B W F E P1 P2 P0 ФD0 T G0. (Unit : m Part No. Size mm (inch) A B W F E P1 P2 P0 ФD0 T G0. Current Sensing Resistors, Metal Plate Type (Unit : m Part No. Size mm (inch) A B W F E P1 P2 P0 ФD0 T G0. P P2 P0 ФD0 T G0. Ф D0 T G0. T G0. Current Sensing Resistors, Metal Plate Type Current Sensing Resistors, Metal Plate Type F E P1 P2 P0 ФD0 T G0. Ф D0 T G0. T G0. Current Sensing Resistors (inch) A B W F E P1 P2 P0 ФD0 T G0. F G0. P G0. Ф D0 T G0. T G0. Current G0. Current G0. T G0. Current G0. Current G0. Current G0. T G0. Current G0. Current G0. T G0. T G0. Current G0. T G0. T G0. T G0. Current G0. T G0. T G0. T G0. Current G0. T G	Part No.	Size mm (inch)	Α	В	W	F	Е		P ₁	P_2	P ₀	φD_0	Т						
Chip Resistors / Precision Chip / Low Resistance / High Power / Anti-Surge / Anti-Pulse / Anti-Sulfurated (Unit : m Part No. Size mm (inch) A B W F E P₁ P₂ P₀ Φ D₀ T 0 ERD1141 3225 2.80±0.20 3.50±0.20 8.00±0.30 3.50±0.05 8.00±0.30 3.50±0.05 8.00±0.30 1.00±0.10 1	ERJXGN	0402	0.25±0.05	0.45±0.05	4.00±0.20	1.80±0.05	0.90±0.	10 1.00	±0.10	1.00±0.10	2.00±0.10	0.80±0.10	0.5 max						
Chip Resistors / Precision Chip / Low Resistance / High Power / Anti-Surge / Anti-Pulse / Anti-Sulfurated (Unit : m Part No. Size mm (inch) A B W F E P₁ P₂ P₀ φ D₀ T q R314□ 14	Fmhoss	ed Carri	er Tani	na (4	mm Pi	tch)													
Part No. Size mm (inch) A B W F E P1 P2 P0 φ D0 T Q R314□ 3225 2.80±0.20 3.50±0.20 8.00±0.30 3.50±0.05 8.00±0.05 1.00							Anti-Surc	ıe / Ani	ti-Pulse	- / Anti-Sı	lfurated	(I In:	t . mm)						
R014	•									-			φD_1						
R3 14		,				-	_	. 1	. 2	. 0	Ψ 50	•	1.00						
RID 12		3223	2.00±0.20	3.30±0.20	0.00±0.50	J.J0±0.05	-						+0.10/0						
1.00±0.10 1.		4532	3.50±0.20	4.80±0.20															
ERJ□1D ERJB1 ERJC1 ERJC1 ERJD1 O Current Sensing Resistors, Metal Plate Type Current Sensing Resistors, Metal Plate Type Fart No. Size mm (inch) ERJMB1 2550 2.90±0.20 5.40±0.20 12.00 ±0.30 5.50±0.10 ±0.10 1.75 ±0.10 ±0.																			
SENDIT	ERJ12S	5025		5.30±0.20	5.30±0.20								1 00+0 10						
12.00			2.80±0.20			5.30±0.20	5.30±0.20	5.30±0.20	5.30±0.20	5.30±0.20	5.30±0.20	5.30±0.20							
ERJD1						5.50±0.20	±0.10	±0.10	±0.05	5 ±0.10	+0.10/0		15 min						
ERJIT 6432 3.60±0.20 6.90±0.20 1.10±0.10 1.10±0.20 1.10±		2550			±0.30														
ERJ□1T 6432 3.60±0.20 6.90±0.20 1.1																			
ERJA1 3264 3.50±0.20 6.80±0.20 1.1		6432	3.60±0.20	6.90±0.20															
◆ Current Sensing Resistors, Metal Plate Type (Unit: m Part No. Size mm (inch) A B W F E P₁ P₂ P₀ φ D₀ T q ERJMB1 2550 2.90±0.20 5.40±0.20 12.00 ±0.30 5.50±0.10 1.75 ±0.10 4.00 ±0.10 2.00 ±0.05 4.00 ±0.10 1.50 ±0.10 1.55±0.20 1.55±0.20 ERJMS4 6432 3.50±0.20 6.90±0.20 12.00 ±0.30 5.50±0.10 ±0.10 ±0.10 ±0.05 ±0.10 +0.10/0 1.60±0.20 1. Φ Chip Resistor Array / Chip Resistor Networks (Unit: m Part No. Size mm (inch) A B W F E P₁ P₂ P₀ Φ D₀ T Q EXBS8V 5022 2.80±0.20 5.70±0.20 12.00 ±0.30 ±0.10 ±0.10 ±0.05 ±0.10 ±0.10 ±0.10/0 1.10±0.20 1.10±0.20 EXBE 4021 2.50±0.20 4.40±0.20 ±0.30 5.50±0.20 ±0.10 ±0.10 ±0.10 ±0.10 ±0.10 ±0.10 ±0.10 ±0.10	ERJL1W											1.60±0.10							
Part No. Size mm (inch) A B W F E P ₁ P ₂ P ₀ φ D ₀ T Q ERJMB1 2550 2.90±0.20 5.40±0.20 12.00 ±0.30 5.50±0.10 1.75 ±0.10 4.00 ±0.10 2.00 ±0.05 4.00 ±0.05 1.50 ±0.10 1.55±0.20 1.55±0.20 1.60±0.20 1. Φ Chip Resistor Array / Chip Resistor Networks (Unit : m Part No. Size mm (inch) A B W F E P ₁ P ₂ P ₀ Φ D ₀ T Q EXBS8V 5022 2.80±0.20 5.70±0.20 12.00 ±0.30 1.75 ±0.10 4.00 ±0.10 2.00 ±0.10 4.00 ±0.10 1.50 ±0.10 1.6 max. ±0.10 1.10±0.20	ERJA1	3264	3.50±0.20	6.80±0.20								1.10±0.20							
Part No. Size mm (inch) A B W F E P ₁ P ₂ P ₀ φ D ₀ T Q ERJMB1 2550 2.90±0.20 5.40±0.20 12.00 ±0.30 5.50±0.10 1.75 ±0.10 4.00 ±0.10 2.00 ±0.05 4.00 ±0.05 1.50 ±0.10 1.55±0.20 1.55±0.20 1.60±0.20 1. Φ Chip Resistor Array / Chip Resistor Networks (Unit : m Part No. Size mm (inch) A B W F E P ₁ P ₂ P ₀ Φ D ₀ T Q EXBS8V 5022 2.80±0.20 5.70±0.20 12.00 ±0.30 1.75 ±0.10 4.00 ±0.10 2.00 ±0.10 4.00 ±0.10 1.50 ±0.10 1.6 max. ±0.10 1.10±0.20	● Current S	ensina Resist	ors Metal	Plate Tyne								/ 11							
ERJMB1 2550 2.90±0.20 5.40±0.20 12.00 ±0.30 5.50±0.10 1.75 4.00 2.00 4.00 1.50 1.55±0.20 1.55±0.20 1.75 4.00 2.00 4.00 1.50 1.55±0.20 1.60±0.20 1			T	1	W	F	Е	P₁	P2	Po	ωD_0		φD_1						
● Chip Resistor Array / Chip Resistor Networks Part No. Size mm (inch) A B W F E P₁ P₂ P₀ φ D₀ T EXBSSV 5022 2.80±0.20 5.70±0.20 1.200 ±0.30 5.50±0.20 1.200 ±0.30 5.50±0.20 1.200 ±0.10 ±0.10 ±0.10 ±0.05 ±0.10 ±0.1	ERJMB1	2550		5.40±0.20	12.00						, ,	1.55±0.20	——————————————————————————————————————						
Part No. Size mm (inch) A B W F E P ₁ P ₂ P ₀ φ D ₀ T φ EXBS8V 5022 2.80±0.20 5.70±0.20 \pm 0.30 \pm 0.30 \pm 0.10 \pm 0.10 \pm 0.10 \pm 0.05 \pm 0.10 \pm 0.	ERJMS4	6432	3.50±0.20	6.90±0.20		5.50±0.10	±0.10					1.60±0.20	1.5 min						
Part No. Size mm (inch) A B W F E P ₁ P ₂ P ₀ φ D ₀ T φ EXBS8V 5022 2.80±0.20 5.70±0.20 \pm 0.30 \pm 0.30 \pm 0.10 \pm 0.10 \pm 0.10 \pm 0.05 \pm 0.10 \pm 0.	● Chin Resi	stor Array / C	hin Resisto	r Network	5		•			•		(Uni	t·mm)						
EXBS8V 5022 2.80 \pm 0.20 5.70 \pm 0.20 12.00 \pm 0.30 5.50 \pm 0.20 1.75 4.00 2.00 4.00 1.50 1.6 max. 1.6 max. 1.6 max. 1.6 max. 1.10 \pm 0.10 \pm 0.1						F	Е	P ₁	P ₂	P ₀	φD_0		φD_1						
EXBE 4021 2.50 ± 0.20 4.40 ± 0.20 ±0.30 2.50 ± 0.20 2.50 ± 0.2	EXBS8V	5022	2.80±0.20	5.70±0.20					_			1.6 max.	, 1						
± 0.30 ± 0.10 ± 0.05 ± 0.10 $\pm 0.10/0$ $\pm 0.10/0$ $\pm 0.10/0$ $\pm 0.10/0$ $\pm 0.10/0$ $\pm 0.10/0$	EXBE	4021				5.50±0.20							1.5 min						
	EXBA	6431			±0.30		±0.10	±0.10	10 ±0.05	±0.10	+0.10/0	1.10±0.20	.20 1.5 min.						



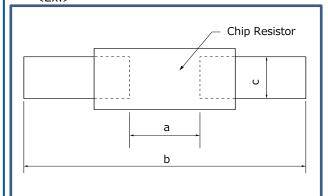
Taping Reel



Tape width(W)	Dimensions (mm)						
rape widen(w)	φΑ	φN	φС	W_1	W_2		
4 mm width	180.0±3.0			4.5±0.5	7.0±0.5		
8 mm width	180.0 0/-1.5	60.0+1.0/0	60.0+1.0/0	60.0+1.0/0	13.0±0.2	9.0+1.0/0	11.4±1.0
12 mm width	160.0 0/-1.5		13.0±0.2	13.0+1.0/0	15.4±1.0		
24 mm width	380.0±2.0	80.0±1.0		25.4±1.0	29.4±1.0		

Recommended Land Pattern

• An example of a land pattern for the Rectangular Type is shown below.



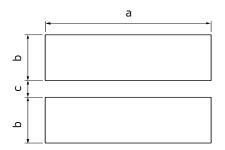
High power (double-sided resistive elements structure) to	20

Part No.			ensions(mm)		
raicivo.	inch	а	b	С	
ERJ2LW/2BW	1005 0402	0.52	1.4 to 1.6	0.4 to 0.6	
ERJ3LW/3BW	1608 0603	0.5 to 0.8	2.5 to 2.7	0.9 to 1.1	
ERJ6LW		0.6 to 0.8	3.2 to 3.8	1.1 to 1.4	
ERJ6BW	2012 0805	0.9	3.2 to 3.8	1.1 to 1.4	
ERJ6CW (10 to 13 mΩ)		0.7 to 0.9	3.2 to 3.8	1.1 to 1.4	
ERJ6CW (15 to 30 mΩ)		0.9 to 1.1	3.2 to 3.8	1.1 to 1.4	
ERJ8BW					
ERJ8CW (10 to 16 mΩ)	3216 1206	1.2	4.4 to 5.0	1.3 to 1.8	
ERJ8CW (18 to 50 mQ)		2.0 to 2.6	4.4 to 5.0	1.2 to 1.8	

Size	Dimensions(mm)			
mm/inch	a	b	С	
0402/01005	0.15 to 0.20	0.5 to 0.7	0.20 to 0.25	
0603/0201	0.3 to 0.4	0.8 to 0.9	0.25 to 0.35	
1005/0402	0.5 to 0.6	1.4 to 1.6	0.4 to 0.6	
1608/0603	0.7 to 0.9	2.0 to 2.2	0.8 to 1.0	
2012/0805	1.0 to 1.4	3.2 to 3.8	0.9 to 1.4	
3216/1206	2.0 to 2.4	4.4 to 5.0	1.2 to 1.8	
3225/1210	2.0 to 2.4	4.4 to 5.0	1.8 to 2.8	
4532/1812	3.3 to 3.7	5.7 to 6.5	2.3 to 3.5	
5025/2010	3.6 to 4.0	6.2 to 7.0	1.8 to 2.8	
6432/2512	5.0 to 5.4	7.6 to 8.6	2.3 to 3.5	
6432/2512*	3.6 to 4.0	7.6 to 8.6	2.3 to 3.5	

* ERJL1W

An example of a land pattern for High Power Chip Resistors / Wide Terminal Type is shown below.

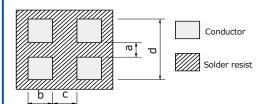


Part No.	Dimensions(mm)				
rait No.	a	b	С		
ERJA1	6.4	1.70	0.60		
ERJB1					
ERJC1 ⁽¹⁾	5.0	1.30	0.75		
ERJD1 ⁽²⁾					
ERJB2	3.2	0.95	0.70		
ERJD2 ⁽²⁾	3.2	0.95	0.70		
ERJB3	2.0	0.80	0.60		

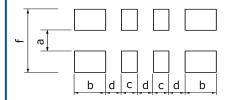
- $(1) \ {\it Anti-Sulfurated \ High \ Power \ Chip \ Resistors/Wide \ Terminal \ Type}$
- (2) Low TCR High Power Chip Resistors/Wide Terminal Type

Recommended Land Pattern

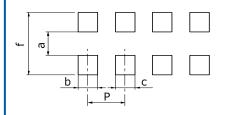
• An example of a land pattern for Chip Resistor Array, Anti-Sulfurated Chip Resistor Array and Chip Attenuator is shown below.



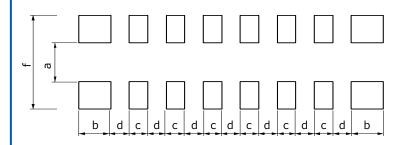
	Part No.	Dimensions(mm)					
rait No.	a	b	С	d			
	EXB14V	0.20	0.30	0.30	0.80 to 0.90		
	EXB14A	0.30	0.30	0.30	0.80 to 0.90		
	EXB24V						
	EXBU24	0.5	0.35 to 0.40	0.30	1.4 to 1.5		
	FXB24A						



Part No.		Dimensions(mm)				
rait No.	a	b	С	d	f	
EXB28V EXBU28	0.40	0.525	0.25	0.25	1.40	
EXBN8V	0.45 to 0.50	0.35 to 0.38	0.25	0.25	1.40 to 2.00	



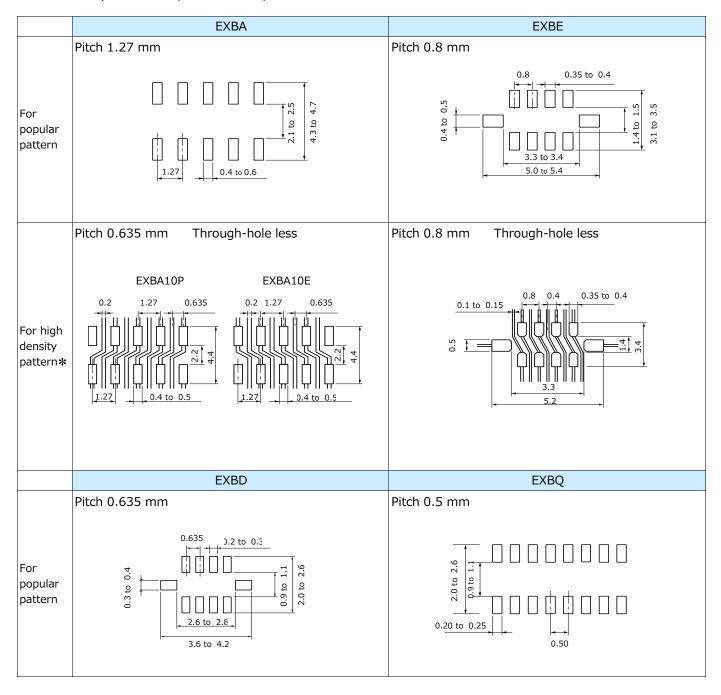
Part No.	Dimensions(mm)							
rait No.	a	b	С	f	Р			
EXB18V	0.20 to 0.30	0.15 to 0.20	0.15 to 0.20	0.80 to 0.90	0.40			
EXBV4V EXBV8V	0.7 to 0.9	0.4 to 0.45	0.4 to 0.45	2 to 2.4	0.80			
EXB34V EXB38V EXBU34 EXBU38	0.7 to 0.9	0.4 to 0.5	0.4 to 0.5	2.2 to 2.6	0.80			
EXBS8V	1 to 1.2	0.5 to 0.75	0.5 to 0.75	3.2 to 3.8	1.27			



Part No.		Dimensions(mm)					
Part No.	a	b	С	d	f		
EXB2HV	1.00	0.425	0.25	0.25	2.00		
EXBU2H	1.00	0.425	0.25	0.25	2.00		

Recommended Land Pattern

• An example of a land pattern for Chip Resistor Networks is shown below.



* When designing high density land patterns, examine the reliability of isolation among the lines and adopt the chip resistor networks.



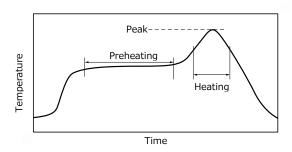
Recommended Soldering Conditions

Recommendations and precautions are described below.

Rectagular Type

• Recommended soldering conditions for reflow

- Reflow soldering shall be performed a maximum of two times.
- •Please contact us for additional information when used in conditions other than those specified.
- •Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



For soldering (Example: Sn/Pb)

	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s
Main heating	Above 200 ℃	30 s to 40 s
Peak	235 ± 5 ℃	max. 10 s

For lead-free soldering (Example : Sn/Ag/Cu)

		- 1 31 1	
	Temperature	Time	
Preheating	150 ℃ to180 ℃	60 s to 120 s	
Main heating	Above 230 ℃	30 s to 40 s	
Peak	max. 260 ℃	max. 10 s	

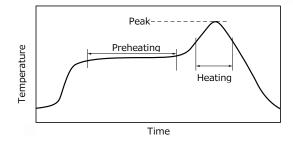
Recommended soldering conditions for flow

	For soldering		For lead-free soldering	
	Temperature	Time	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s	150 ℃ to 180 ℃	60 s to 120 s
Soldering	245 ± 5 ℃	20 s to 30 s	max. 260 ℃	max. 10 s

Chip Resistor Array, Chip Resistor Networks and Chip Attenuator

• Recommended soldering conditions for reflow

- Reflow soldering shall be performed a maximum of two times.
- •Please contact us for additional information when used in conditions other than those specified.
- •Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



For soldering (Example: Sn/Pb)

	Temperature	Time		
Preheating	140 ℃ to 160 ℃	60 s to 120 s		
Main heating	Above 200 ℃	30 s to 40 s		
Peak	235 ± 5 ℃	max. 10 s		

For lead-free soldering (Example: Sn/Ag/Cu)

3 (1 1 1 3 1 1 1 1 1 1							
	Temperature	Time					
Preheating	150 ℃ to180 ℃	60 s to 120 s					
Main heating	Above 230 ℃	30 s to 40 s					
Peak	max. 260 ℃	max. 10 s					

Flow soldering

We do not recommend flow soldering, because a solder bridge may form. Please contact us regarding flow sol der ing of EXBA series.



Standard for Resistance Value and Resistance Tolerance

Basis Standard

IEC Publication 60062: Marking codes for resistors and capacitors.

IEC Publication 60063: Preferred number series for resistors and capacitors.

JIS C 5062: Marking codes for resistors and capacitors.

JIS C 5063: Preferred number series for resistors and capacitors.

Resistance Values

The resistance values are notched by "Ratio" below in each series.

Series	Resistance Tolerance (Standard)	Ratio	Remarks
E6	±20 %	⁶ √10=1.46	
E12	±10 %	¹²√10=1.21	
E24	± 5 %	24√10=1.10	Please refer to standard resistance values shown on this catalog.
E48	± 2 %	48√10=1.05	Shows on and educage
E96	± 1 %	96√10=1.02	

How to express the resistance value with a Panasonic part number

The resistance value expressed in ohms is iden tified by a three digit number or a four digit number.

The last digit specifies the number of zeroes to follow.

The letter "R" shall be used as the decimal point for less than 10 Ω .

The examples of a three digit number

The examples of a circle digit flamber							
Resistance Code	Value in ohms (Ω)						
R56	0.56						
5R6	5.6						
100	10						
271	270						
102	1 k						
273	27 k						
104	100 k						
275	2.7 M						
106	10 M						
107	100 M						

The examples of a four digit number

Resistance Code	Value in ohms (Ω)		
R562	0.562		
5R62	5.62		
56R2	56.2		
1000	100		
2711	2.71 k		
1002	10 k		
2713	271 k		
1004	1 M		
2751	2.71 M		
1006	100 M		

How to express the resistance tolerance with a Panasonic part number

The resistance tolerance is identified by a single letter in accordance with the following table and the code is placed just before the resistance code in the following examples.

Tolerance Code	Tolerance (%)	Examples
W	±0.05	W1001 : 1000 Ω±0.05 %
В	±0.1	B1001 : 1000 Ω±0.1 %
С	±0.25	C1001 : 1000 Ω±0.25 %
D	±0.5	D1001 : 1000 Ω±0.5 %
F	±1	F1001 : 1000 Ω±1 %
G	±2	G1001 : 1000 Ω±2 %
J	±5	J101 : 100 Ω±5 %
K	±10	K101 : 100 Ω±10 %
М	±20	M101 : 100 Ω±20 %

Standard Resistance Values

E6	E12	E24	E48	E96	E6	E12	E24	E48	E96	E6	E12	E24	E48	E96
10	10	10	100	100				215	215				464	464
				102	22	22	22		221	47	47	47		475
			105	105				226	226				487	487
				107					232					499
		11	110	110			24	237	237			51	511	511
				113			24		243					523
			115	115				249	249				536	536
	12	10	-	118					255					549
	12	12	121	121				261	261		56	56	562	562
				124		27	27		267					576
			127	127		27	27	274	274				590	590
		13	-	130					280					604
			133	133				287	287			62	619	619
				137					294					634
			140	140			30	301	301				649	649
				143					309					665
			147	147				316	316	68	68	68	681	681
15	15	15	_	150	33	33	33		324					698
			154	154	33	33	33	332	332				715	715
		16	-	158					340					732
		10	162	162				348	348			75	750	750
				165			36		357					768
			169	169			30	365	365				787	787
				174					374		82	82	-	806
	18	18	178	178		39	39	383	383		02	02	825	825
	10	10		182					392					845
			187	187				402	402				866	866
				191					412					887
			196	196			43	422	422			91	909	909
		20		200					432					931
			205	205				442	442				953	953
				210					453					976
	I .		1	<u> </u>		l .	1	<u>I</u>	<u> </u>			I .	I .	

CAUTION AND WARNING

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 Before use of any of these components for equipment that requires a high degree of safety, such as medical instruments, aerospace equipment, disaster-prevention equipment, security equipment, vehicles (automobile, train, vessel), please be sure to contact our sales representative corporation.
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RCWP11002K00FKS3 RCWP12061K00FKS2 3520510RJT 352075KJT M55342K11B9E53RUL RMC16-102JT RMC1JPTE TR0603MR
075K1L 5-2176094-4 35202K7JT WF06Q1000FTL ERJ-S03J1R0V ERJ-S14J4R7U CHP2512L4R30GNT CPCC10270R0JE32

RCWP11001K00FKS3